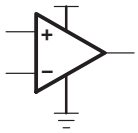
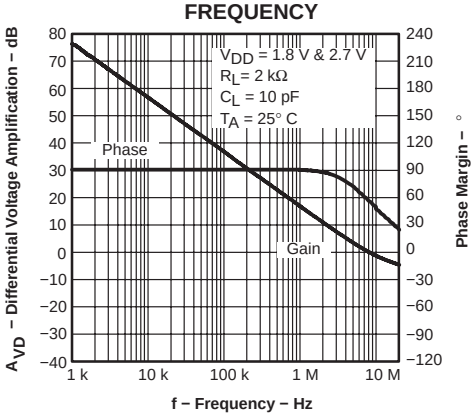
- **Supply Voltage Range . . . 1.8 V to 3.6 V**
- **Rail-to-Rail Input/Output**
- **High Bandwidth . . . 8 MHz**
- **High Slew Rate . . . 4.8 V/μs**
- **V_{ICR} Exceeds Rails . . . −0.2 V to V_{DD}+ 0.2**
- **Supply Current . . . 650 μA/Channel**
- **Input Noise Voltage . . . 9 nV/√Hz at 10 kHz**
- **Specified Temperature Range:**
  0°C to 70°C . . . Commercial Grade
  −40°C to 125°C . . . Industrial Grade
- **Ultrasmall Packaging**
- **Universal Operational Amplifier EVM**

Operational Amplifier



DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE VS FREQUENCY



description

The TLV278x single supply operational amplifiers provide rail-to-rail input and output capability. The TLV278x takes the minimum operating supply voltage down to 1.8 V over the extended industrial temperature range (−40°C to 125°C) while adding the rail-to-rail output swing feature. The TLV278x also provides 8 MHz bandwidth from only 650 μA of supply current. The maximum recommended supply voltage is 3.6 V, which allows the devices to be operated from (±1.8 V supplies down to ±0.9 V) two rechargeable cells.

The combination of wide bandwidth, low noise, and low distortion makes it ideal for high speed and high resolution data converter applications.

All members are available in PDIP, SOIC, and the newer, smaller SOT-23 (singles), MSOP (duals), and TSSOP (quads).

FAMILY PACKAGE TABLE

DEVICE	V_{DD} [V]	V_{IO} [μV]	I_{DD}/ch [μA]	I_{IB} [pA]	GBW [MHz]	SLEW RATE [V/μs]	$V_{n, 1\ kHz}$ [nV/√Hz]	I_O [mA]	SHUTDOWN	RAIL-TO-RAIL
TLV278x(A)	1.8−3.6	250	650	2.5	8	5	18	10	Y	I/O
TLV276x(A)	1.8−3.6	550	20	3	0.5	0.23	95	5	Y	I/O
TLV246x(A)	2.7−6	150	550	1300	6.4	1.6	11	25	Y	I/O
TLV247x(A)	2.7−6	250	600	2.5	2.8	1.5	15	20	Y	I/O
TLV244x(A)	2.7−10	300	750	1	1.81	1.4	16	2	—	O
TLV277x(A)	2.5−5.5	360	1000	2	5.1	10.5	17	6	Y	O

TLV2780 and TLV2781 AVAILABLE OPTIONS(1)

T_A	V_{IO}max AT 25°C	PACKAGED DEVICES			
		SMALL OUTLINE (D)†	SOT-23 (DBV)‡	SOT-23 SYMBOL	PLASTIC DIP (P)
0°C to 70°C	3000 μV	TLV2780CD TLV2781CD	TLV2780CDBV TLV2781CDBV	VASC VATC	— —
-40°C to 125°C	3000 μV	TLV2780ID TLV2781ID	TLV2780IDBV TLV2781IDBV	VASI VATI	TLV2780IP TLV2781IP
	2000 μV	TLV2780AID TLV2781AID	— —	— —	— —

† This package is available taped and reeled. To order this packaging option, add an **R** suffix to the part number (e.g., TLV2780CDR).
‡ This package is only available taped and reeled. For standard quantities (3,000 pieces per reel), add an **R** suffix (i.e., TLV2780CDBVR). For smaller quantities (250 pieces per mini-reel), add a **T** suffix to the part number (e.g. TLV2780CDBVT).

TLV2782 and TLV2783 AVAILABLE OPTIONS(1)

T_A	V_{IO}max AT 25°C	PACKAGED DEVICES						
		SMALL OUTLINE† (D)	MSOP (DGK)†	MSOP SYMBOL	MSOP (DGS)†	MSOP SYMBOL	PLASTIC DIP (N)	PLASTIC DIP (P)
0°C to 70°C	3000 μV	TLV2782CD TLV2783CD	TLV2782CDGK —	xxTIADL —	— TLV2783CDGS	— xxTIADN	— —	— —
−40°C to 125°C	3000 μV	TLV2782ID TLV2783ID	TLV2782IDGK —	xxTIADM —	— TLV2783IDGS	— xxTIADO	— TLV2783IN	TLV2782IP —
	2000 μV	TLV2782AID TLV2783AID	— —	— —	— —	— —	— —	— —

† This package is available taped and reeled. To order this packaging option, add an **R** suffix to the part number (e.g., TLV2782CDR).

TLV2784 and TLV2785 AVAILABLE OPTIONS(1)

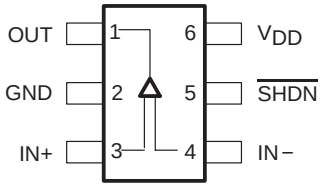
T_A	V_{IO}max AT 25°C	PACKAGED DEVICES		
		SMALL OUTLINE (D)	PLASTIC DIP (N)	TSSOP† (PW)
0°C to 70°C	3000 μV	TLV2784CD TLV2785CD	— —	TLV2784CPW TLV2785CPW
−40°C to 125°C	3000 μV	TLV2784ID TLV2785ID	TLV2784IN TLV2785IN	TLV2784IPW TLV2785IPW
	2000 μV	TLV2784AID TLV2785AID	— —	TLV2784AIPW TLV2785AIPW

† This package is available taped and reeled. To order this packaging option, add an **R** suffix to the part number (e.g., TLV2784CDR).

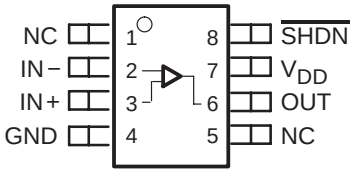
1. For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

TLV278x PACKAGE PINOUTS

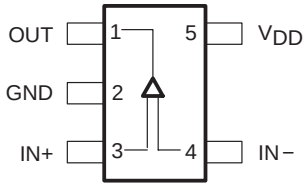
TLV2780
DBV PACKAGE
(TOP VIEW)



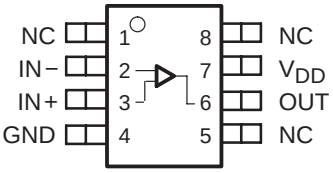
TLV2780
D OR P PACKAGE
(TOP VIEW)



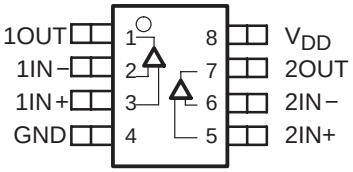
TLV2781
DBV PACKAGE
(TOP VIEW)



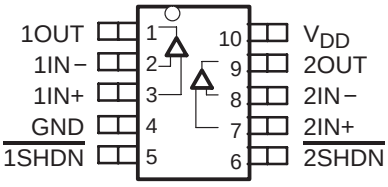
TLV2781
D OR P PACKAGE
(TOP VIEW)



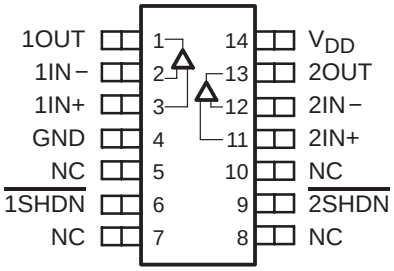
TLV2782
D, DGK, OR P PACKAGE
(TOP VIEW)



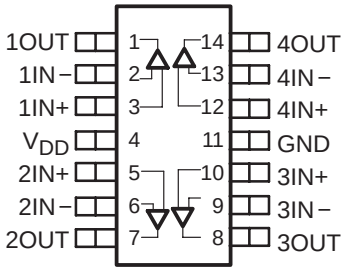
TLV2783
DGS PACKAGE
(TOP VIEW)



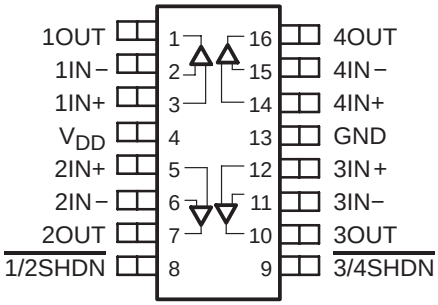
TLV2783
D OR N PACKAGE
(TOP VIEW)



TLV2784
D, N, OR PW PACKAGE
(TOP VIEW)



TLV2785
D, N, OR PW PACKAGE
(TOP VIEW)



NC − No internal connection

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{DD} (see Note 1) . . . . . 4 V
Differential input voltage, V_{ID} . . . . . $\pm V_{DD}$
Input current, I_I (any input) . . . . . ± 10 mA
Output current, I_O . . . . . ± 10 mA
Continuous total power dissipation . . . . . See Dissipation Rating Table
Operating free-air temperature range, T_A: C-suffix . . . . . 0°C to 70°C
I-suffix . . . . . −40°C to 125°C
Maximum junction temperature, T_J . . . . . 150°C
Storage temperature range, T_{stg} . . . . . −65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds . . . . . 260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values, except differential voltages, are with respect to GND.

DISSIPATION RATING TABLE

PACKAGE	Θ_{JC} (°C/W)	Θ_{JA} (°C/W)	$T_A \le 25°C$ POWER RATING	$T_A = 125°C$ POWER RATING
D (8)	38.3	176	710 mW	142 mW
D (14)	26.9	122.3	1022 mW	204.4 mW
D (16)	25.7	114.7	1090 mW	218 mW
DBV (5)	55	324.1	385 mW	77.1 mW
DBV (6)	55	294.3	425 mW	85 mW
DGK (8)	54.2	259.9	481 mW	96.2 mW
DGS (10)	54.1	257.7	485 mW	97 mW
N (14, 16)	32	78	1600 mW	320.5 mW
P (8)	41	104	1200 mW	240.4 mW
PW (14)	29.3	173.6	720 mW	144 mW
PW (16)	28.7	161.4	774 mW	154.9 mW

recommended operating conditions

			MIN	MAX	UNIT
Supply voltage, V_{DD}	Single supply		1.8	3.6	V
	Split supply		±0.9	±1.8	
Common-mode input voltage range, V_{ICR}			−0.2	V_{DD}+0.2	V
Operating free-air temperature, T_A	C-suffix		0	70	°C
	I-suffix		−40	125	
Shutdown on/off voltage level‡	V_{IH}	V_{DD} < 2.7 V	0.75V_{DD}		V
		V_{DD} = 2.7 to 3.6 V	2		
	V_{IL}			0.6	

‡ Relative to GND.

electrical characteristics at specified free-air temperature, V_{DD} = 1.8 V, 2.7 V (unless otherwise noted)

dc performance

PARAMETER		TEST CONDITIONS		T_A†	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	$V_O = V_{DD}/2$, R_L = 2 kΩ, R_S = 50 Ω	TLV278x	25°C		250	3000	μV
				Full range			4500	
			TLV278xA	25°C		250	2000	
				Full range			3000	
α_{VIO}	Temperature coefficient of input offset voltage					8		μV/°C
CMRR	Common-mode rejection ratio	V_{IC} = 0 to V_{DD}, R_S = 50 Ω	V_{DD} = 1.8 V	25°C	50	76		dB
				Full range	50			
			V_{DD} = 2.7 V/ 3.6 V	25°C	55	80		
				Full range	50			
		V_{IC} = 1.2 V to V_{DD}, R_S = 50 Ω	V_{DD} = 2.7 V/ 3.6 V	25°C	70	100		
				Full range	70			
A_{VD}	Large-signal differential voltage amplification	R_L = 2 kΩ, $V_{O(PP)}$ = 1 V	V_{DD} = 1.8 V	25°C	200	600		V/mV
				Full range	50			
			V_{DD} = 2.7 V/ 3.6 V	25°C	200	1000		
				Full range	70			

† Full range is 0°C to 70°C for the C-suffix and −40°C to 125°C for the I-suffix. If not specified, full range is −40°C to 125°C.

input characteristics

PARAMETER		TEST CONDITIONS		T_A†	MIN	TYP	MAX	UNIT
I_{IO}	Input offset current	$V_O = V_{DD}/2$, R_L = 2 kΩ, R_S = 50 Ω		25°C		2.5	15	pA
			TLV278xC	Full range			100	
			TLV278xI	Full range			300	
I_{IB}	Input bias current			25°C		2.5	15	pA
			TLV278xC	Full range			100	
			TLV278xI	Full range			300	
$r_{i(d)}$	Differential input resistance			25°C		1000		GΩ
$C_{i(c)}$	Common-mode input capacitance	f = 1 kHz		25°C		19		pF

† Full range is 0°C to 70°C for the C-suffix and −40°C to 125°C for the I-suffix. If not specified, full range is −40°C to 125°C.

electrical characteristics at specified free-air temperature, V_{DD} = 1.8 V, 2.7 V (unless otherwise noted) (continued)

output characteristics

PARAMETER		TEST CONDITIONS		T_A†	MIN	TYP	MAX	UNIT
V_{OH}	High-level output voltage	I_{OH} = −1 mA	V_{DD} = 1.8 V	25°C	1.7	1.77		V
				Full range	1.63			
			V_{DD} = 2.7 V	25°C	2.6	2.68		
				Full range	2.6			
			V_{DD} = 3.6 V	25°C		3.58		
		I_{OH} = −5 mA	V_{DD} = 1.8 V	25°C	1.5	1.55		
				Full range	1.46			
			V_{DD} = 2.7 V	25°C	2.5	2.55		
				Full range	2.45			
			V_{DD} = 3.6 V	25°C		3.55		
V_{OL}	Low-level output voltage	I_{OL} = 1 mA		25°C			70	mV
				Full range			80	
		I_{OL} = 5 mA	V_{DD} = 1.8 V	25°C		180	240	
				Full range			290	
			V_{DD} = 2.7 V	25°C		120	170	
				Full range			200	
I_O	Output current	V_{DD} = 1.8 V, VO = 0.5 V from	Positive rail	25°C		10		mA
			Negative rail			15		
		V_{DD} = 2.7 V, VO = 0.5 V from	Positive rail			17		
			Negative rail			23		
I_{OS}	Short-circuit output current	Sourcing	V_{DD} = 1.8 V	25°C		13		mA
			V_{DD} = 2.7 V			35		
		Sinking	V_{DD} = 1.8 V			21		
			V_{DD} = 2.7 V			45		

† Full range is 0°C to 70°C for the C-suffix and −40°C to 125°C for the I-suffix. If not specified, full range is −40°C to 125°C.

power supply

PARAMETER		TEST CONDITIONS		T_A†	MIN	TYP	MAX	UNIT
I_{DD}	Supply current (per channel)	$V_O = V_{DD}/2$,	$\overline{SHDN} = V_{DD}$	25°C		650	770	μA
				Full range			820	
k_{SVR}	Supply voltage rejection ratio (ΔV_{DD} /ΔV_{IO})	V_{DD} = 1.8 V to 2.7 V, $V_{IC} = V_{DD}/2$	No load,	25°C	60	75		dB
				Full range	58			
		V_{DD} = 2.7 V to 3.6 V, $V_{IC} = V_{DD}/2$	No load,	25°C	75	90		
				Full range	70			
		V_{DD} = 1.8 V to 3.6 V, $V_{IC} = V_{DD}/2$	No load,	25°C	65	80		
				Full range	60			

† Full range is 0°C to 70°C for the C-suffix and −40°C to 125°C for the I-suffix. If not specified, full range is −40°C to 125°C.

electrical characteristics at specified free-air temperature, V_{DD} = 1.8 V, 2.7 V (unless otherwise noted) (continued)

dynamic performance

PARAMETER		TEST CONDITIONS		T_A†	MIN	TYP	MAX	UNIT
UGBW	Unity gain bandwidth	R_L = 2 kΩ,	C_L = 25 pF	25°C		8		MHz
SR+	Positive slew rate at unity gain	$V_{O(PP)}$ = 1 V, R_L = 2 kΩ, C_L = 50 pF	V_{DD} = 1.8 V	25°C	3.3	4.3		V/μs
				Full range	3.1			
			V_{DD} = 2.7 V	25°C	3.8	4.8		
				Full range	3.5			
			V_{DD} = 3.6 V	25°C	4	5		
				Full range	3.6			
SR−	Negative slew rate at unity gain	$V_{O(PP)}$ = 1 V, R_L = 2 kΩ, C_L = 50 pF	V_{DD} = 1.8 V	25°C	2.1	2.8		
				Full range	1.89			
			V_{DD} = 2.7 V	25°C	2.2	2.8		
				Full range	1.97			
			V_{DD} = 3.6 V	25°C	3.5	4.2		
				Full range	3.4			
ϕ_m	Phase margin	R_L = 2 kΩ,	C_L = 25 pF	25°C		58°		
	Gain margin					8		dB
t_s	Settling time	V_{DD} = 1.8 V, $V_{(STEP)PP}$ = 1 V, A_V = −1, C_L = 10 pF, R_L = 2 kΩ	0.1%	25°C		1.7		μs
			0.01%			2.8		
		V_{DD} = 2.7 V, $V_{(STEP)PP}$ = 1 V, A_V = −1, C_L = 10 pF, R_L = 2 kΩ	0.1%			1.7		
			0.01%			2.4		

† Full range is 0°C to 70°C for the C-suffix and −40°C to 125°C for the I-suffix. If not specified, full range is −40°C to 125°C.

noise/distortion performance

PARAMETER		TEST CONDITIONS		T_A	MIN	TYP	MAX	UNIT
THD + N	Total harmonic distortion plus noise	$V_{O(PP)}$ = V_{DD}/2, R_L = 2 kΩ, f = 10 kHz	A_V = 1	25°C		0.055%		
			A_V = 10			0.08%		
			A_V = 100			0.45%		
V_n	Equivalent input noise voltage	f = 1 kHz				18		nV/√Hz
		f = 10 kHz				9		
I_n	Equivalent input noise current	f = 1 kHz				0.9		fA/√Hz

shutdown characteristics

PARAMETER		TEST CONDITIONS	T_A†	MIN	TYP	MAX	UNIT
$I_{DD(SHDN)}$	Supply current, per channel in shutdown mode (TLV2780, TLV2783, TLV2785)	$\overline{SHDN}$ = 0 V	25°C		900	1400	nA
			Full range			1700	
$t_{(on)}$	Amplifier turnon time‡	R_L = 2 kΩ	25°C		800		ns
$t_{(off)}$	Amplifier turnoff time‡	R_L = 2 kΩ			200		

† Full range is 0°C to 70°C for the C-suffix and −40°C to 125°C for the I-suffix. If not specified, full range is −40°C to 125°C.
‡ Disable time and enable time are defined as the interval between application of the logic signal to $\overline{SHDN}$ and the point at which the supply current has reached half its final value.

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	vs Common-mode input voltage	1, 2
CMRR	Common-mode rejection ratio	vs Frequency	3
V_{OH}	High-level output voltage	vs High-level output current	4, 6
V_{OL}	Low-level output voltage	vs Low-level output current	5, 7
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	8
Z_o	Output impedance	vs Frequency	9
I_{DD}	Supply current	vs Supply voltage	10
I_{DD}	Supply current	vs Free-air temperature	11
PSRR	Power supply rejection ratio	vs Frequency	12
A_{VD}	Differential voltage amplification & phase	vs Frequency	13
	Gain-bandwidth product	vs Free-air temperature	14
SR	Slew rate	vs Supply voltage	15
		vs Free-air temperature	16, 17
ϕ_m	Phase margin	vs Load capacitance	18
V_n	Equivalent input noise voltage	vs Frequency	19
	Voltage-follower large-signal pulse response	vs Time	20
	Voltage-follower small-signal pulse response	vs Time	21
	Inverting large-signal pulse response	vs Time	22
	Inverting small-signal pulse response	vs Time	23
	Crosstalk	vs Frequency	24
	Shutdown forward & reverse isolation	vs Frequency	25
$I_{DD(SHDN)}$	Shutdown supply current	vs Free-air temperature	26
$I_{DD(SHDN)}$	Shutdown supply current	vs Supply voltage	27
$I_{DD(SHDN)}$	Shutdown supply current/output voltage	vs Time	28

TYPICAL CHARACTERISTICS

INPUT OFFSET VOLTAGE vs COMMON-MODE INPUT VOLTAGE

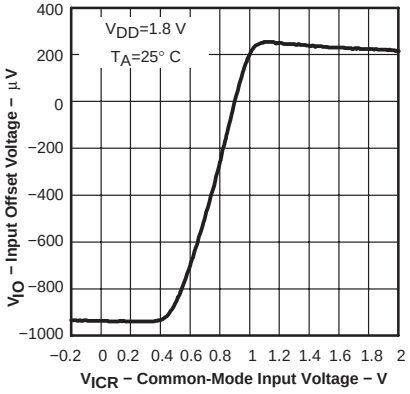


Figure 1

INPUT OFFSET VOLTAGE vs COMMON-MODE INPUT VOLTAGE

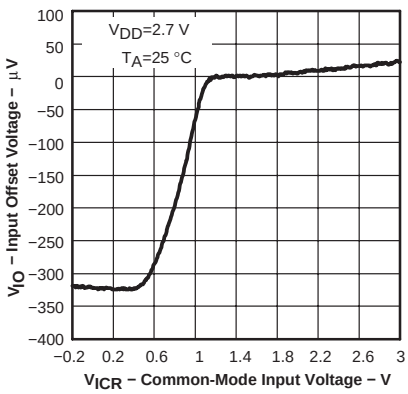


Figure 2

COMMON-MODE REJECTION RATIO vs FREQUENCY

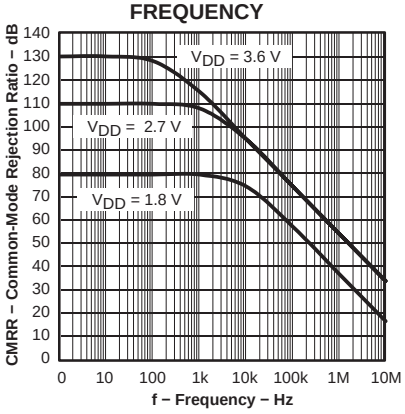


Figure 3

HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT

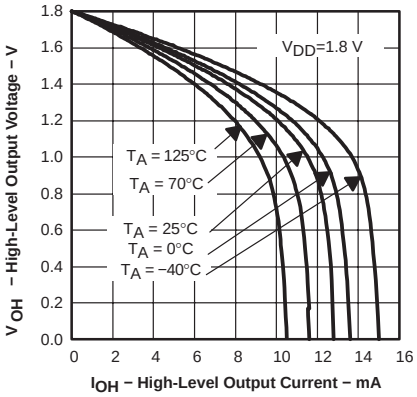


Figure 4

LOW-LEVEL OUTPUT VOLTAGE vs LOW-LEVEL OUTPUT CURRENT

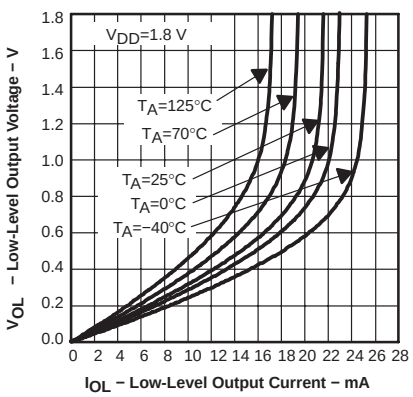


Figure 5

HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT

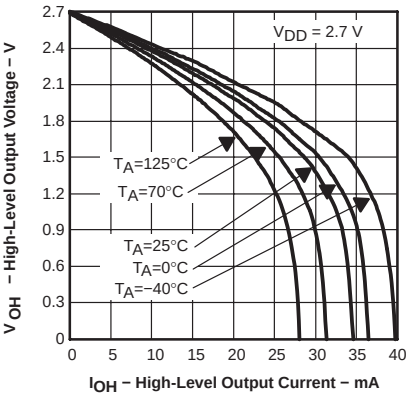


Figure 6

LOW-LEVEL OUTPUT VOLTAGE vs LOW-LEVEL OUTPUT CURRENT

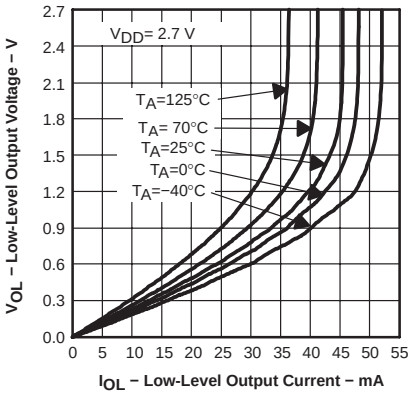


Figure 7

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE vs FREQUENCY

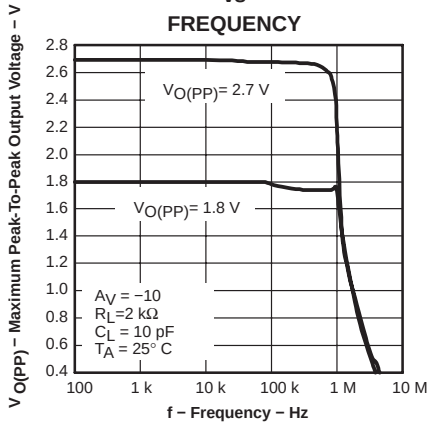


Figure 8

OUTPUT IMPEDANCE vs FREQUENCY

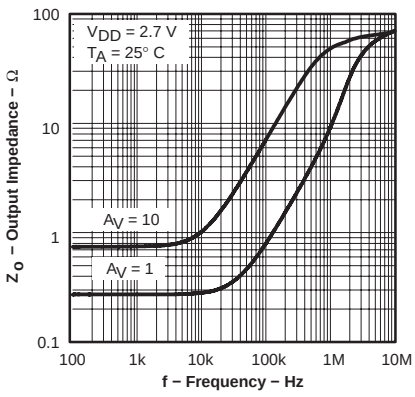


Figure 9

TYPICAL CHARACTERISTICS

SUPPLY CURRENT vs SUPPLY VOLTAGE

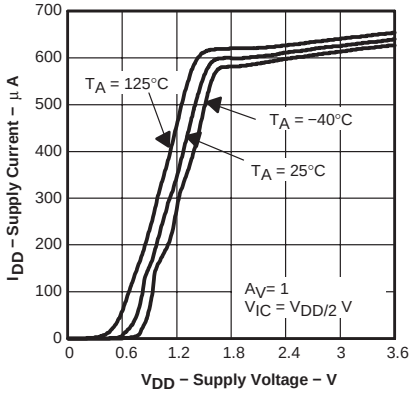


Figure 10

SUPPLY CURRENT vs FREE-AIR TEMPERATURE

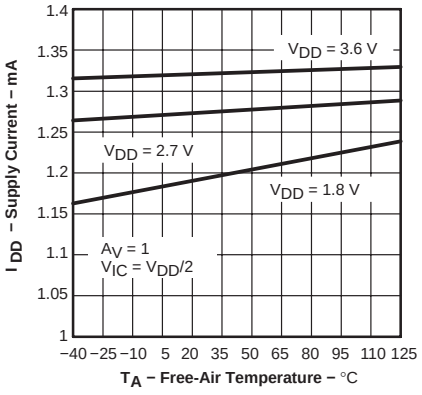


Figure 11

POWER SUPPLY REJECTION RATIO vs FREQUENCY

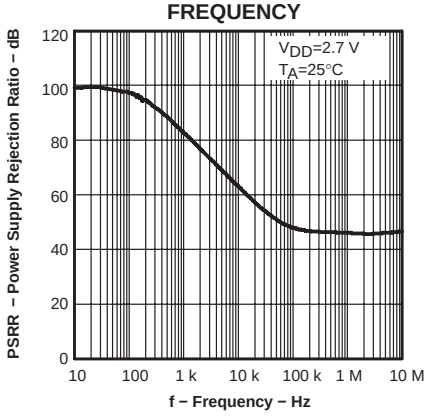


Figure 12

DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE vs FREQUENCY

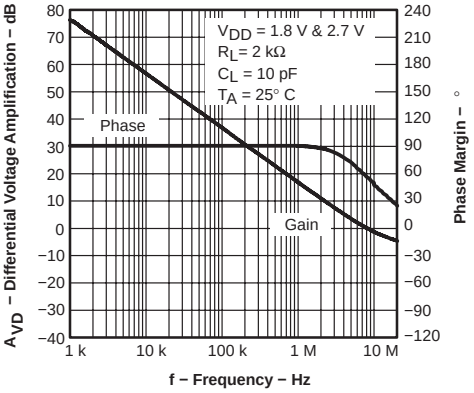


Figure 13

GAIN-BANDWIDTH PRODUCT vs FREE-AIR TEMPERATURE

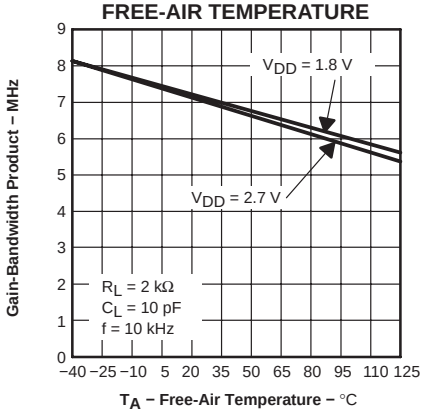


Figure 14

SLEW RATE vs SUPPLY VOLTAGE

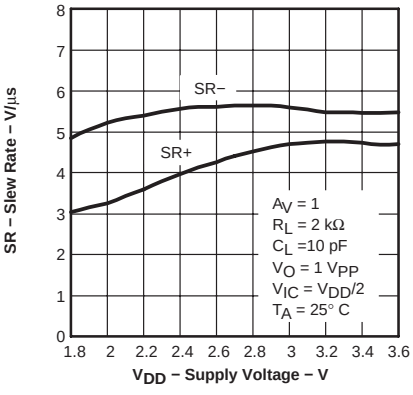


Figure 15

SLEW RATE vs FREE-AIR TEMPERATURE

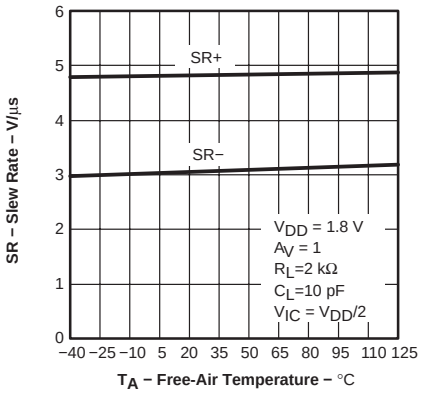


Figure 16

SLEW RATE vs FREE-AIR TEMPERATURE

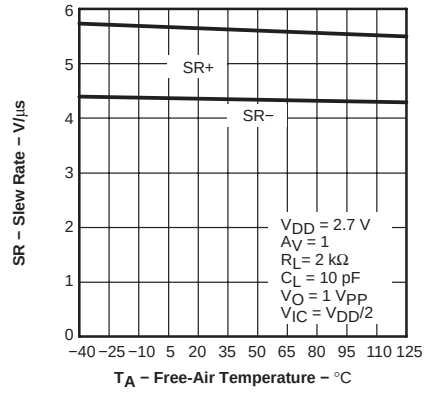


Figure 17

TYPICAL CHARACTERISTICS

PHASE MARGIN vs LOAD CAPACITANCE

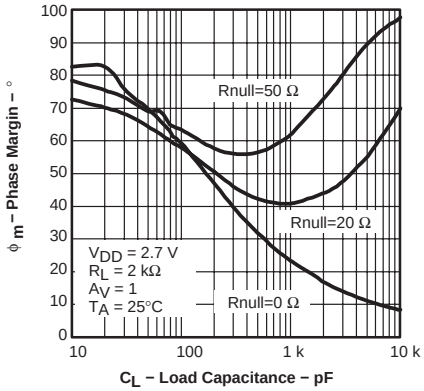


Figure 18

EQUIVALENT INPUT NOISE VOLTAGE vs FREQUENCY

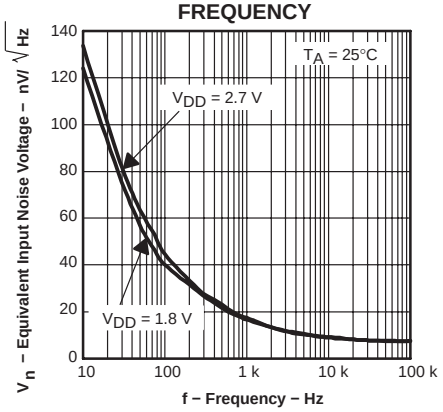


Figure 19

VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE vs TIME

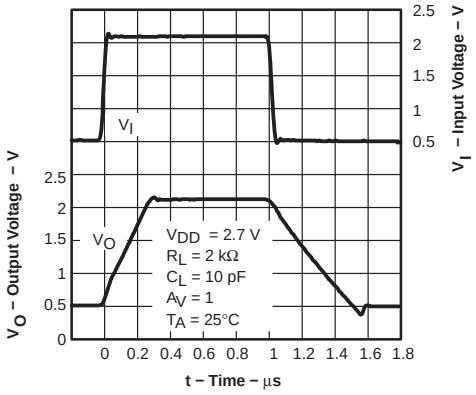


Figure 20

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE vs TIME

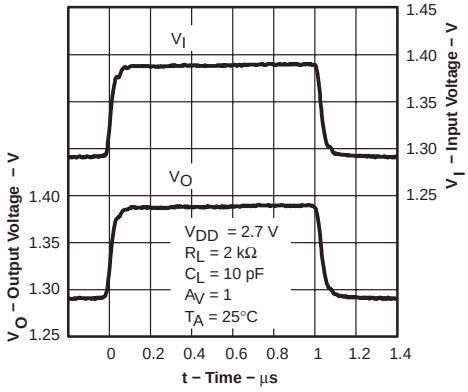


Figure 21

INVERTING LARGE-SIGNAL PULSE RESPONSE vs TIME

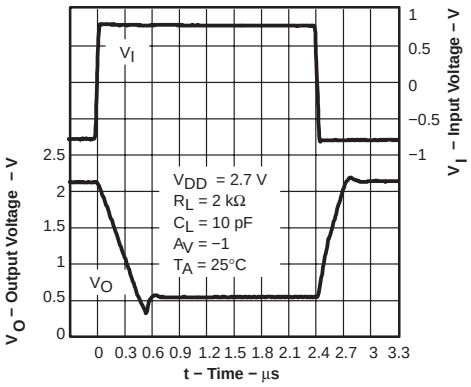


Figure 22

INVERTING SMALL-SIGNAL PULSE RESPONSE vs TIME

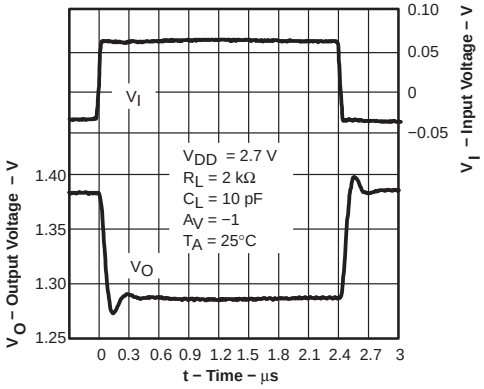


Figure 23

TYPICAL CHARACTERISTICS

CROSSTALK vs FREQUENCY

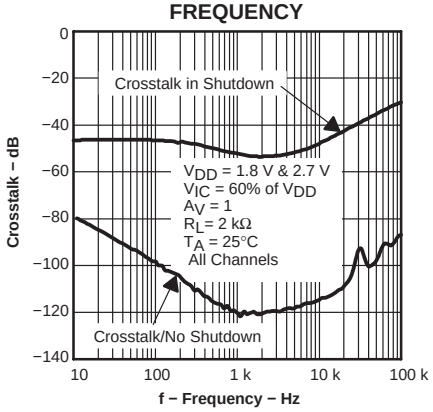


Figure 24

SHUTDOWN FORWARD AND REVERSE ISOLATION vs FREQUENCY

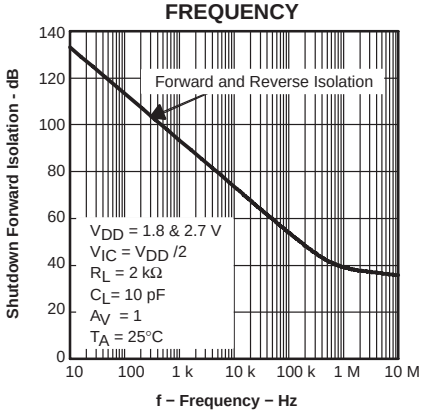


Figure 25

SHUTDOWN SUPPLY CURRENT vs FREE-AIR TEMPERATURE

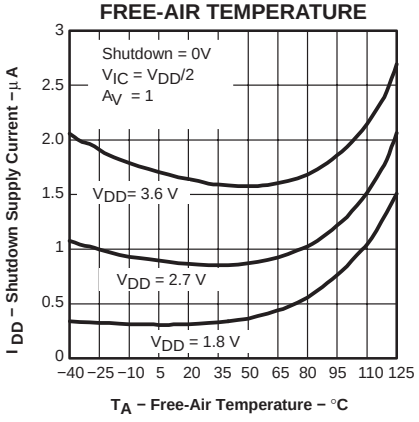


Figure 26

SHUTDOWN SUPPLY CURRENT vs SUPPLY VOLTAGE

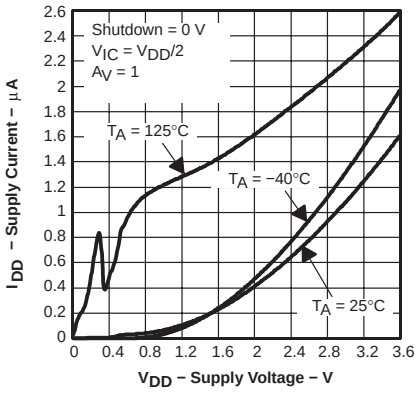


Figure 27

SHUTDOWN SUPPLY CURRENT / OUTPUT VOLTAGE vs TIME

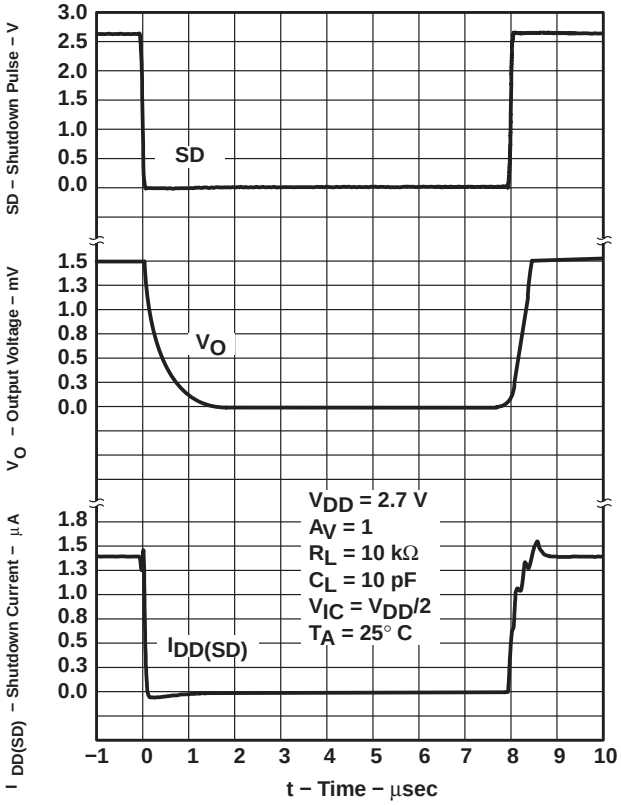


Figure 28

PARAMETER MEASUREMENT INFORMATION

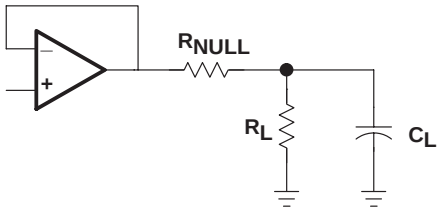


Figure 29

APPLICATION INFORMATION

driving a capacitive load

When the amplifier is configured in this manner, capacitive loading directly on the output will decrease the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series (R_{NULL}) with the output of the amplifier, as shown in Figure 30.

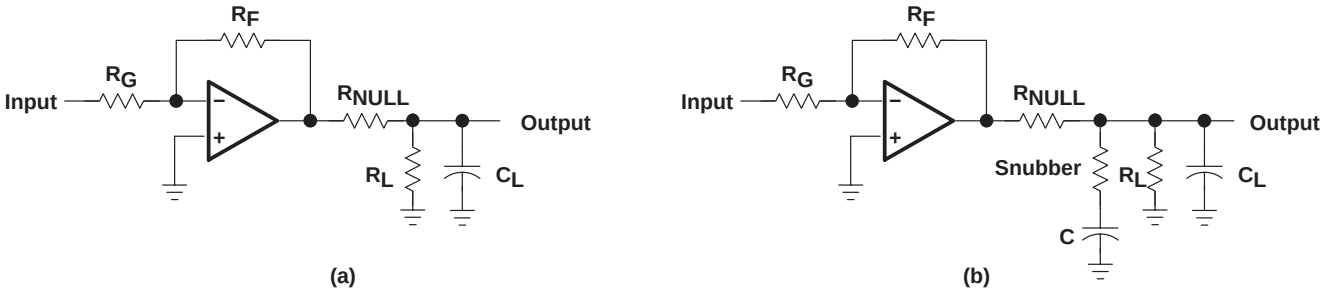
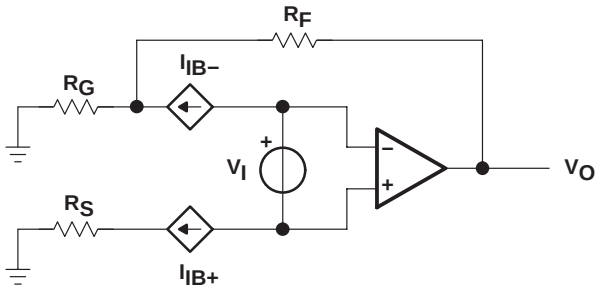


Figure 30. Driving a Capacitive Load

offset voltage

The output offset voltage, (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:



$$V_{OO} = V_{IO}\left(1 + \left(\frac{R_F}{R_G}\right)\right) \pm I_{IB+}\, R_S\left(1 + \left(\frac{R_F}{R_G}\right)\right) \pm I_{IB-}\, R_F$$

Figure 31. Output Offset Voltage Model

APPLICATION INFORMATION

general configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 32).

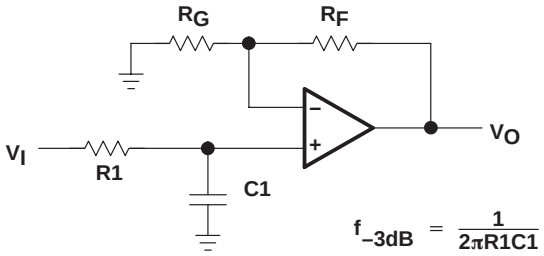


Figure 32. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

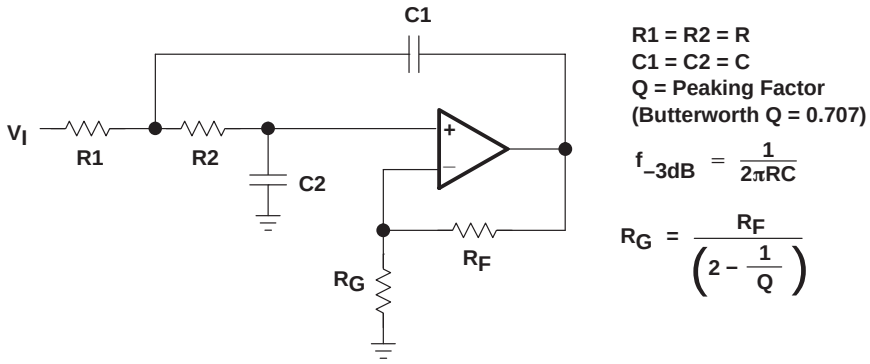


Figure 33. 2-Pole Low-Pass Sallen-Key Filter

APPLICATION INFORMATION

circuit layout considerations

To achieve the levels of high performance of the TLV278x, follow proper printed-circuit board design techniques. A general set of guidelines is given in the following.

- Ground planes − It is highly recommended that a ground plane be used on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling − Use a 6.8-μF tantalum capacitor in parallel with a 0.1-μF ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1-μF ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1-μF capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets − Sockets can be used but are not recommended. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- Short trace runs/compact part placements − Optimum high performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- Surface-mount passive components − Using surface-mount passive components is recommended for high performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout, thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.

shutdown function

Three members of the TLV278x family (TLV2780/3/5) have a shutdown terminal for conserving battery life in portable applications. When the shutdown terminal is tied low, the supply current is reduced to 900 nA/channel, the amplifier is disabled, and the outputs are placed in a high impedance mode. To enable the amplifier, the shutdown terminal can either be left floating or pulled high. When the shutdown terminal is left floating, care should be taken to ensure that parasitic leakage current at the shutdown terminal does not inadvertently place the operational amplifier into shutdown.

APPLICATION INFORMATION

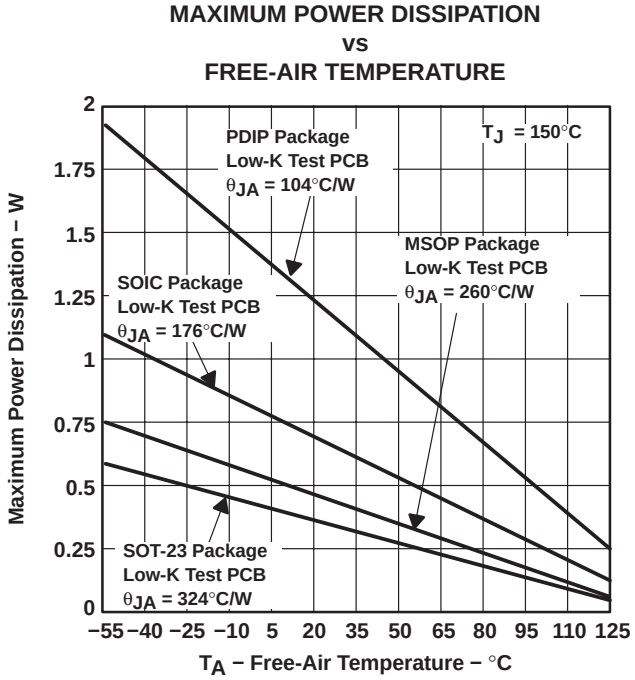
general power dissipation considerations

For a given θ_{JA}, the maximum power dissipation is shown in Figure 34 and is calculated by the following formula:

$$P_D = \left(\frac{T_{MAX} - T_A}{\theta_{JA}} \right)$$

Where:

P_D = Maximum power dissipation of TLV278x IC (watts)
T_{MAX} = Absolute maximum junction temperature (150°C)
T_A = Free-ambient air temperature (°C)
$\theta_{JA} = \theta_{JC} + \theta_{CA}$
θ_{JC} = Thermal coefficient from junction to case
θ_{CA} = Thermal coefficient from case to ambient air (°C/W)



NOTE A: Results are with no air flow and using JEDEC Standard Low-K test PCB.

Figure 34. Maximum Power Dissipation vs Free-Air Temperature

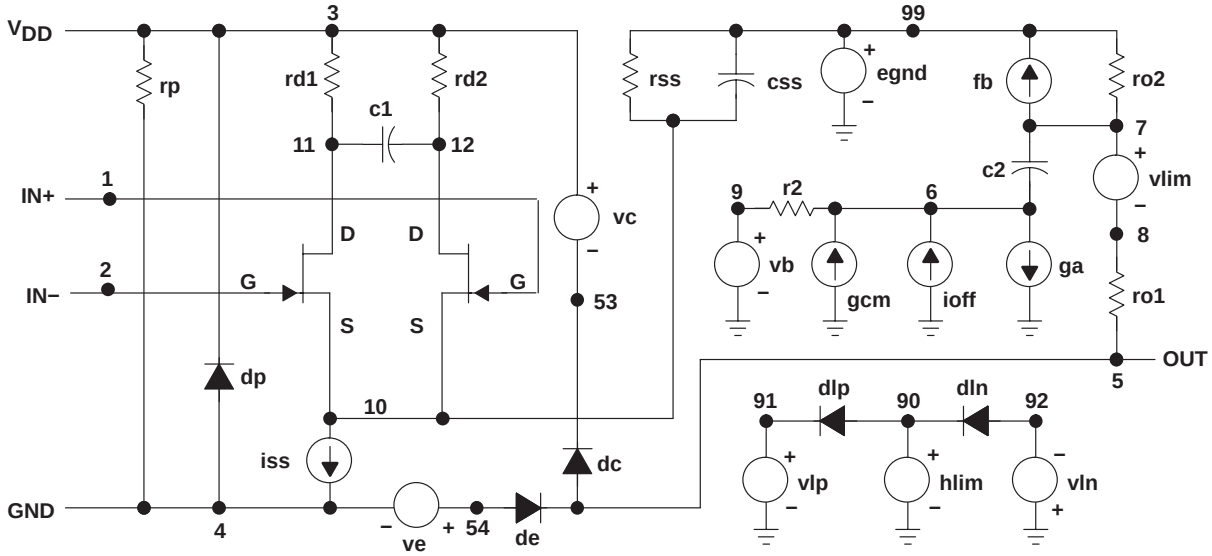
APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim *Parts*™ Release 9.1, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 2) and subcircuit in Figure 35 are generated using TLV278x typical electrical and operating characteristics at T_A = 25°C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 2: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, “Macromodeling of Integrated Circuit Operational Amplifiers,” *IEEE Journal of Solid-State Circuits,* SC-9, 353 (1974).




```
* TLV2782_HVDD operational amplifier ”macromodel” subcircuit
* created using Model Editor release 9.1 on 03/3/00 at 9:47
* Model Editor is an OrCAD product.
*
* connections:   non−inverting input
*                                | inverting input
*                                | | positive power supply
*                                | | | negative power supply
*                                | | | | output
*                                | | | | |
.subckt TLV2782_HVDD             1 2 3 4 5
*
c1      11      12      49.58E−15
c2      6       7       10.200E−12
css     10      99      1.0000E−30
dc      5       53      dy
de      54      5       dy
dlp     90      91      dx
dln     92      90      dx
dp      4       3       dx
egnd    99      0       poly(2) (3,0) (4,0) 0 .5 .5
fb      7       99      poly(5) vb vc ve vlp vln 0
                        41.096E6 −1E3 1E3 41E6
                        −41E6
ga      6       0       11 12  544.75E−6
gcm     0       6       10 99 1.1538E−9
iss     10      4       dc 56.957E−6
hlim    90      0       vlim 1K
j1      11      2       10 jx1
J2      12      1       10 jx2
r2      6       9       100.00E3
rd1     3       11      1.8357E3
rd2     3       12      1.8357E3
ro1     8       5       10
ro2     7       99      10
rp      3       4       2.1845E3
rss     10      99      3.5114E6
vb      9       0       dc 0
vc      3       53      dc .81911
ve      54      4       dc .81911
vlim    7       8       dc 0
vlp     91      0       dc 45.400
vln     0       92      dc 45.400
.model  dx      D(Is=800.00E−18)
.model  dy      D(Is=800.00E−18 Rs=1m Cjo=10p)
.model  jx1     NJF(Is=500.00E−15 Beta=5.2102E−3 Vto=−1)
.model  jx2     NJF(Is=500.00E−15 Beta=5.2102E−3 Vto=−1)
.ends
```

Figure 35. Boyle Macromodel and Subcircuit

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2780CDBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VASC	Samples
TLV2780CDBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VASC	Samples
TLV2780CDBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VASC	Samples
TLV2780IDBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VASI	Samples
TLV2780IDBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VASI	Samples
TLV2780IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	T2780I	Samples
TLV2781CDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VATC	Samples
TLV2781CDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VATC	Samples
TLV2781CDBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VATC	Samples
TLV2781ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	T2781I	Samples
TLV2781IDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VATI	Samples
TLV2781IDBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VATI	Samples
TLV2781IDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VATI	Samples
TLV2781IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	T2781I	Samples
TLV2781IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	T2781I	Samples
TLV2782AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2782AI	Samples
TLV2782CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2782C	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2782CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2782C	Samples
TLV2782CDGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU | CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	ADL	Samples
TLV2782CDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU | CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	ADL	Samples
TLV2782CDGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	ADL	Samples
TLV2782CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2782C	Samples
TLV2782ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2782I	Samples
TLV2782IDGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU | CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	ADM	Samples
TLV2782IDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU | CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	ADM	Samples
TLV2782IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2782I	Samples
TLV2782IP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2782IP	Samples
TLV2783CDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2783C	Samples
TLV2783IDGS	ACTIVE	VSSOP	DGS	10	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ADO	Samples
TLV2783IDGSG4	ACTIVE	VSSOP	DGS	10	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ADO	Samples
TLV2783IDGSR	ACTIVE	VSSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ADO	Samples
TLV2783IN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2783I	Samples
TLV2784AID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2784AI	Samples
TLV2784AIDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2784AI	Samples
TLV2784AIDRG4	ACTIVE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 125		Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2784CPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2784C	Samples
TLV2784ID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2784I	Samples
TLV2784IDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2784I	Samples
TLV2784IPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2784I	Samples
TLV2784IPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2784I	Samples
TLV2785AID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2785AI	Samples
TLV2785CPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2785C	Samples
TLV2785IDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2785I	Samples
TLV2785IN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2785I	Samples
TLV2785INE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2785I	Samples
TLV2785IPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2785I	Samples
TLV2785IPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2785I	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

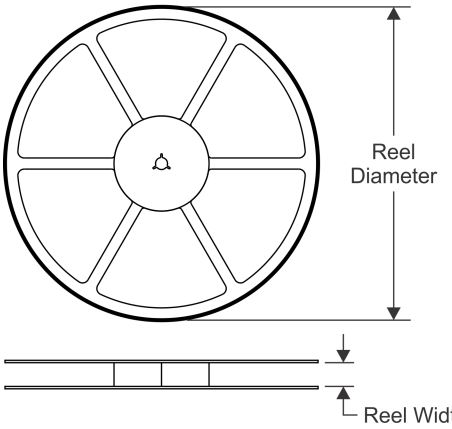
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

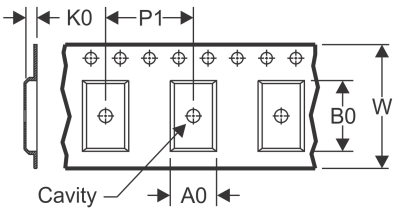
(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

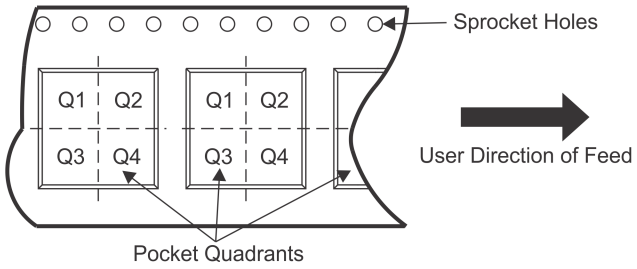


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

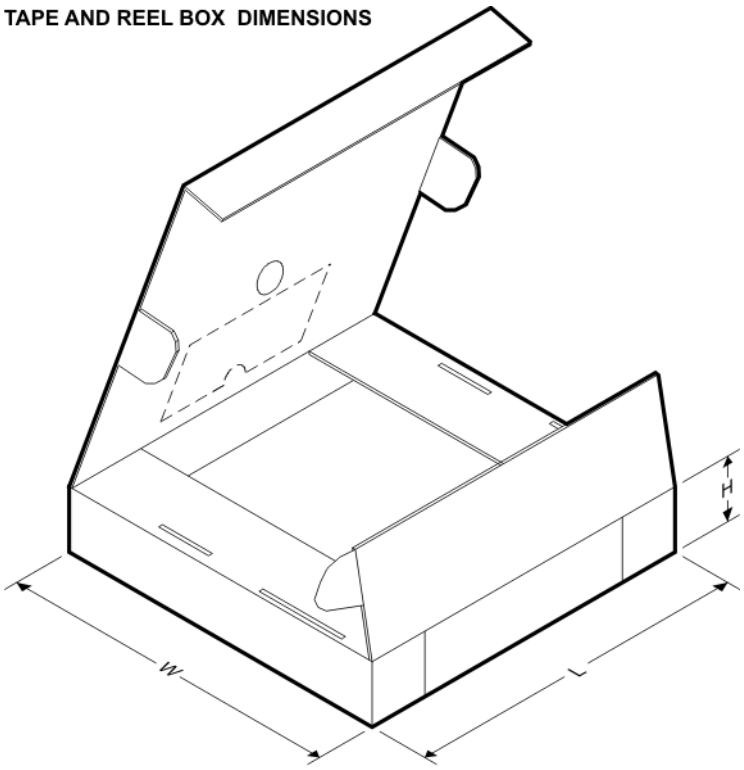


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2780CDBVR	SOT-23	DBV	6	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2780CDBVT	SOT-23	DBV	6	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2780IDBVR	SOT-23	DBV	6	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2780IDBVT	SOT-23	DBV	6	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2780IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2781CDBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2781CDBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2781IDBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2781IDBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2781IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2782CDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2782CDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2782CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2782IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2782IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2782IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2783CDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2783IDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2784AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2784CPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2784IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2784IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2785CPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2785IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TLV2785IPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

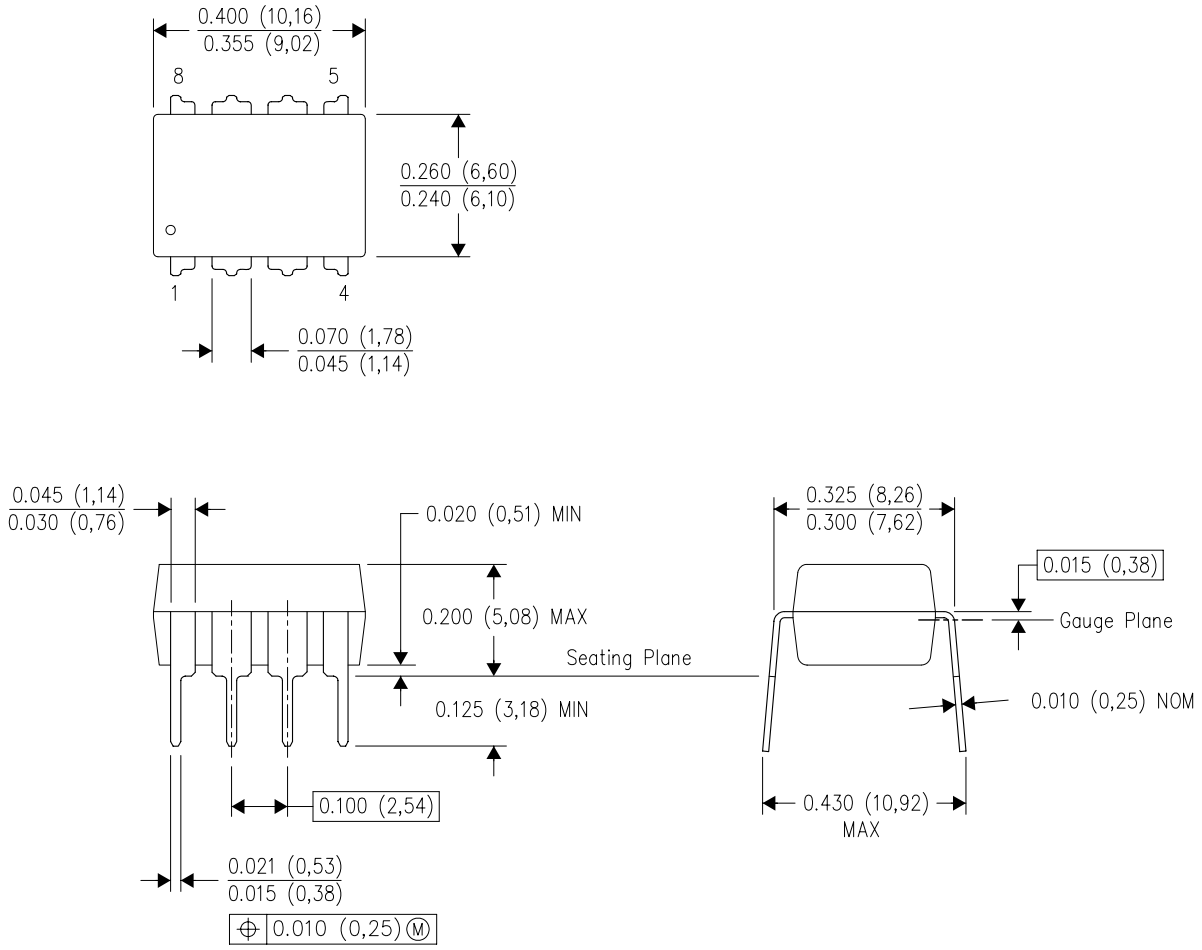


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2780CDBVR	SOT-23	DBV	6	3000	182.0	182.0	20.0
TLV2780CDBVT	SOT-23	DBV	6	250	182.0	182.0	20.0
TLV2780IDBVR	SOT-23	DBV	6	3000	182.0	182.0	20.0
TLV2780IDBVT	SOT-23	DBV	6	250	182.0	182.0	20.0
TLV2780IDR	SOIC	D	8	2500	367.0	367.0	38.0
TLV2781CDBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TLV2781CDBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TLV2781IDBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TLV2781IDBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TLV2781IDR	SOIC	D	8	2500	340.5	338.1	20.6

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2782CDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TLV2782CDGKR	VSSOP	DGK	8	2500	364.0	364.0	27.0
TLV2782CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2782IDGKR	VSSOP	DGK	8	2500	364.0	364.0	27.0
TLV2782IDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TLV2782IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2783CDR	SOIC	D	14	2500	367.0	367.0	38.0
TLV2783IDGSR	VSSOP	DGS	10	2500	358.0	335.0	35.0
TLV2784AIDR	SOIC	D	14	2500	367.0	367.0	38.0
TLV2784CPWR	TSSOP	PW	14	2000	367.0	367.0	35.0
TLV2784IDR	SOIC	D	14	2500	367.0	367.0	38.0
TLV2784IPWR	TSSOP	PW	14	2000	367.0	367.0	35.0
TLV2785CPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
TLV2785IDR	SOIC	D	16	2500	367.0	367.0	38.0
TLV2785IPWR	TSSOP	PW	16	2000	367.0	367.0	35.0

P (R–PDIP–T8) PLASTIC DUAL–IN–LINE PACKAGE

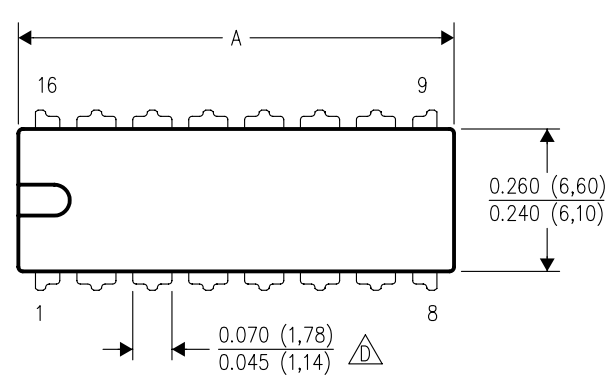


NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001 variation BA.

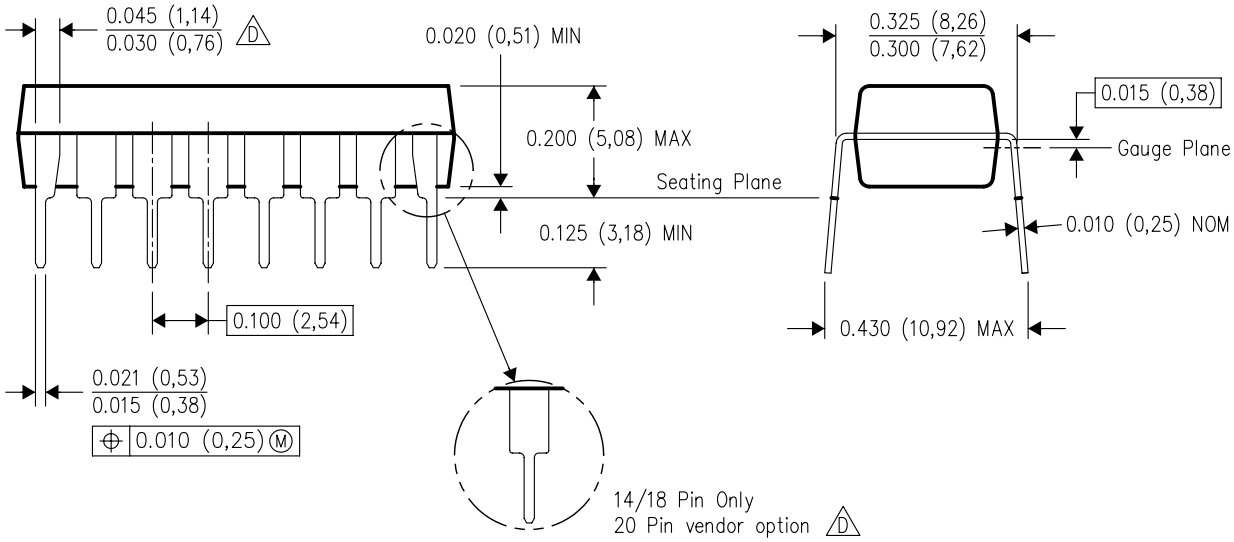
N (R–PDIP–T**)

PLASTIC DUAL–IN–LINE PACKAGE

16 PINS SHOWN



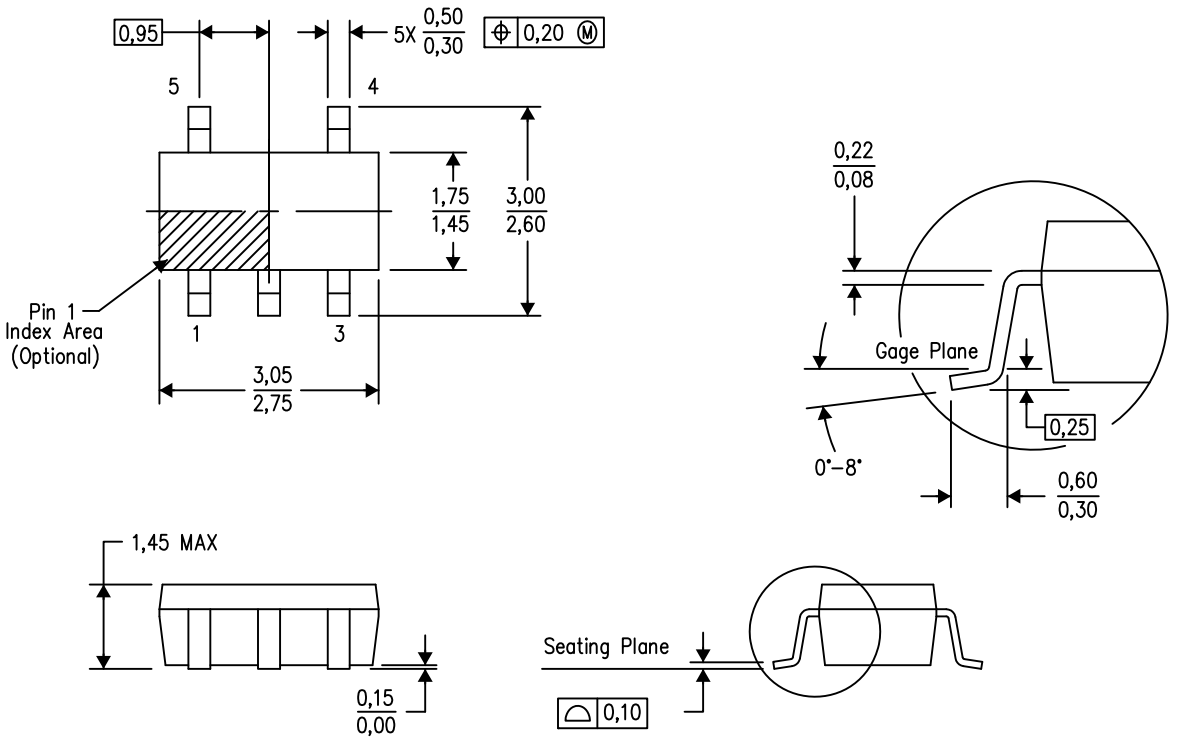
DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS–001 VARIATION (C)	AA	BB	AC	AD



4040049/E 12/2002

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

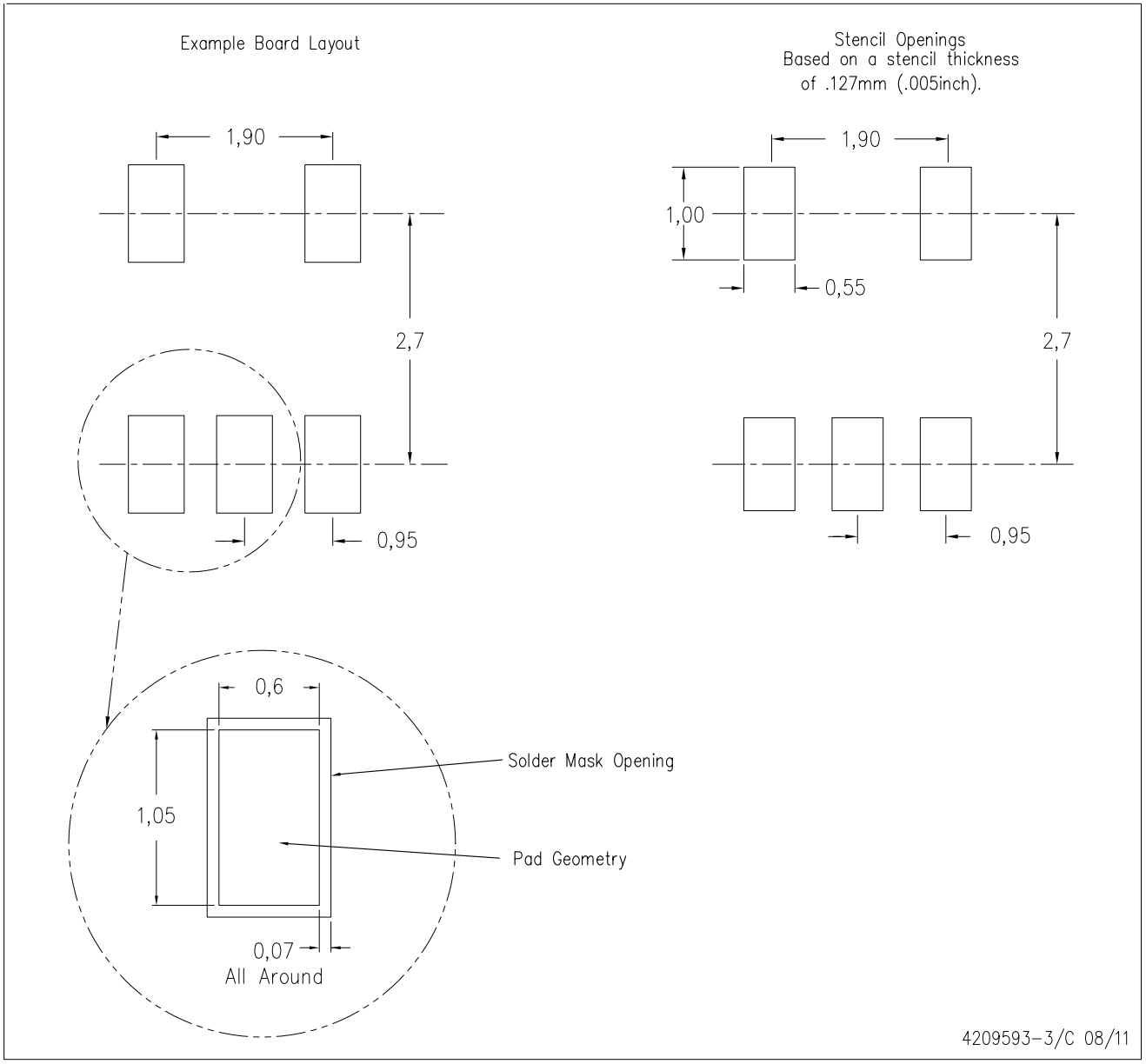
DBV (R–PDSO–G5) PLASTIC SMALL–OUTLINE PACKAGE



4073253–4/N 12/14

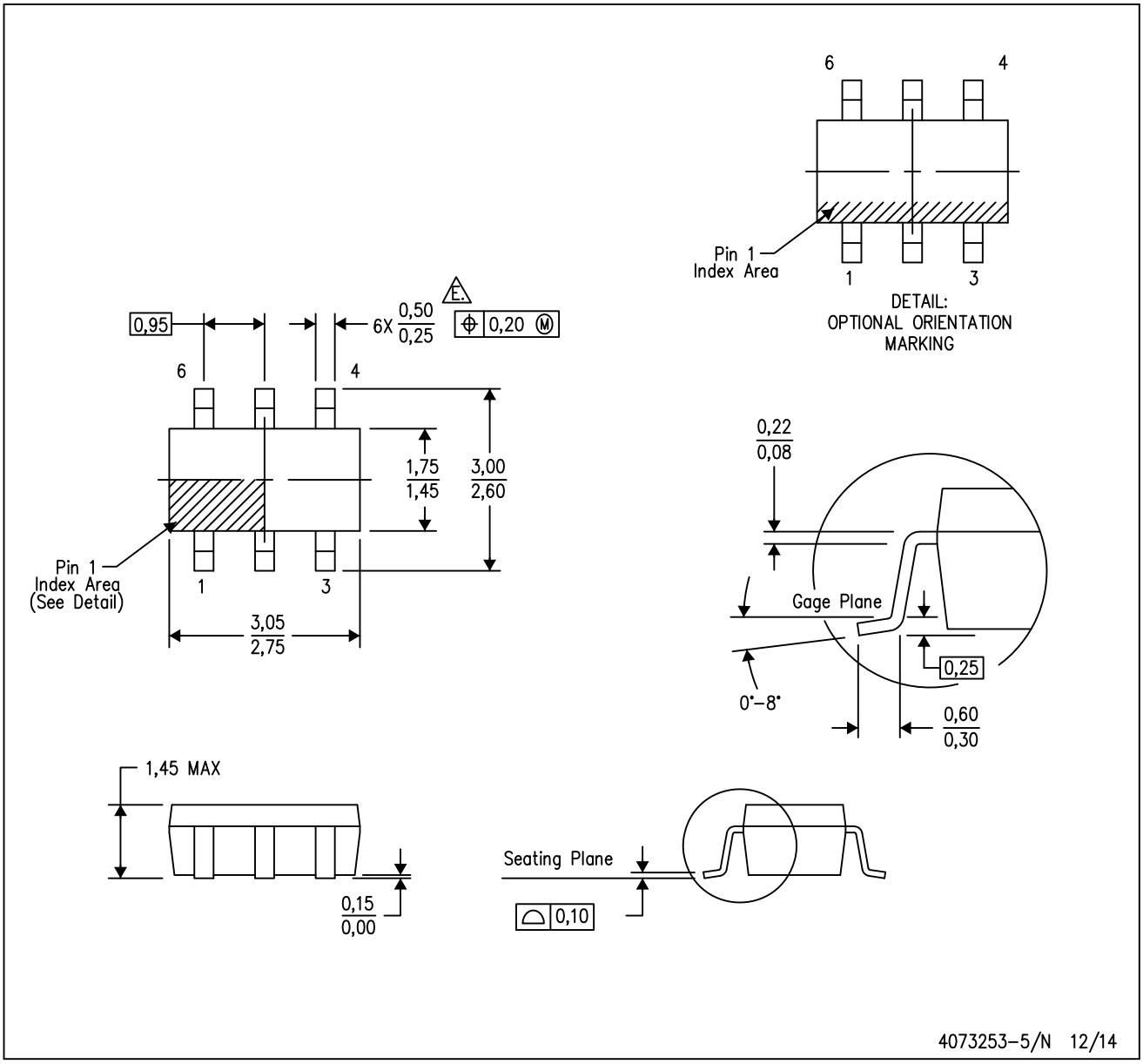
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
D. Falls within JEDEC MO–178 Variation AA.

DBV (R–PDSO–G5) PLASTIC SMALL OUTLINE



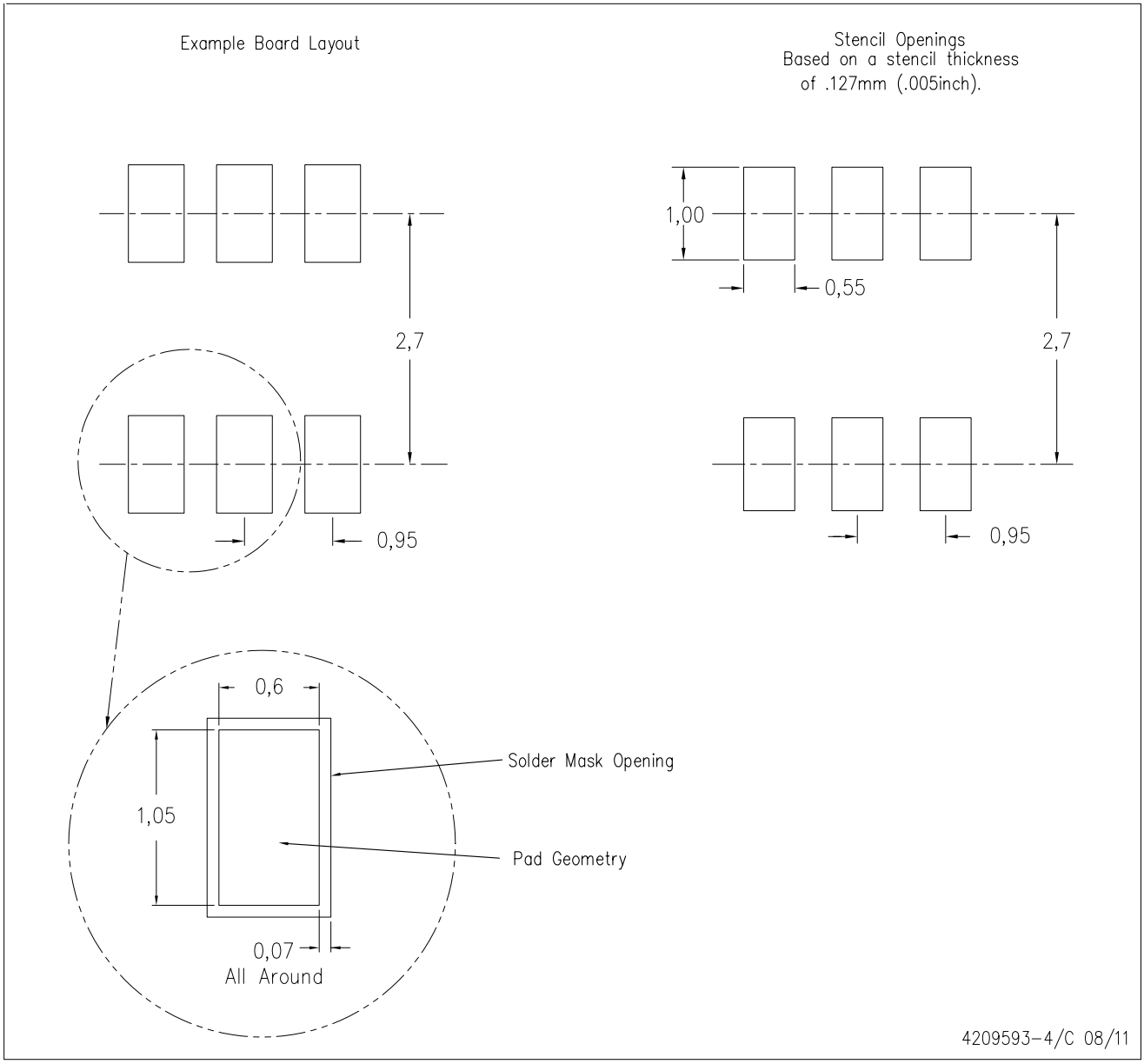
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. Publication IPC–7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC–7525 for other stencil recommendations.

DBV (R–PDSO–G6) PLASTIC SMALL–OUTLINE PACKAGE



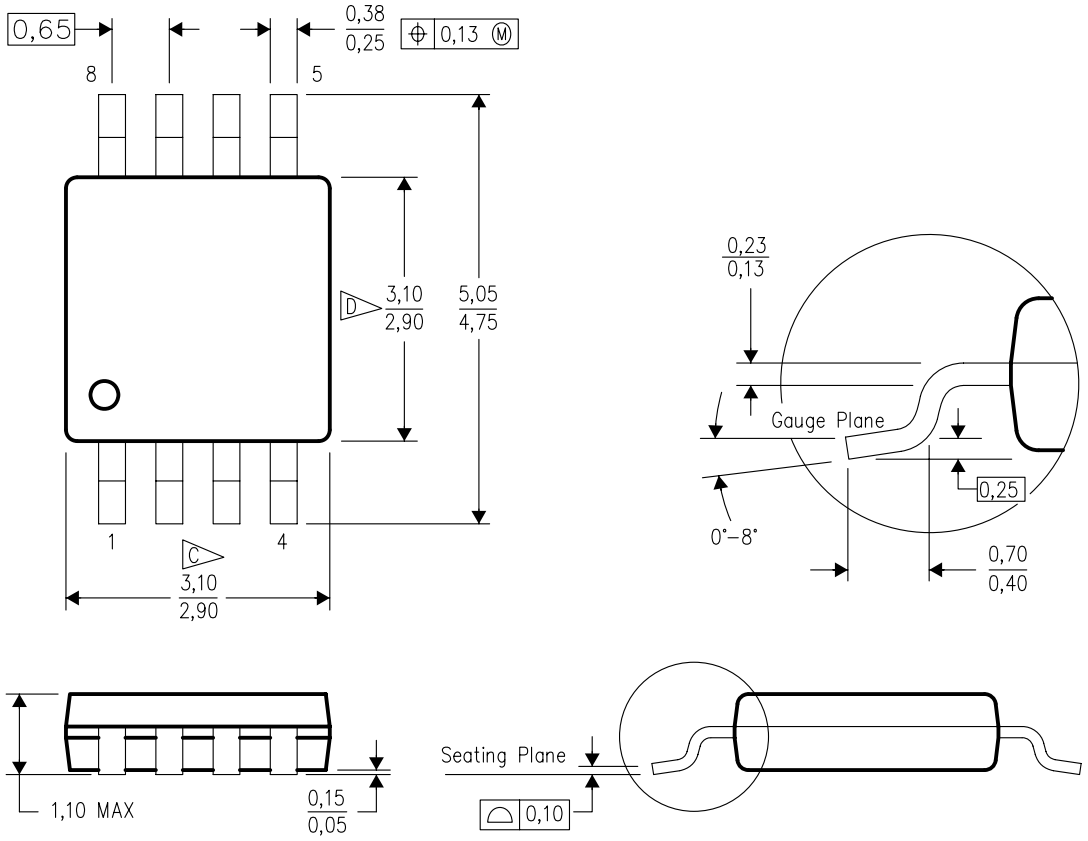
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
E. Falls within JEDEC MO–178 Variation AB, except minimum lead width.

DBV (R–PDSO–G6) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. Publication IPC–7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC–7525 for other stencil recommendations.

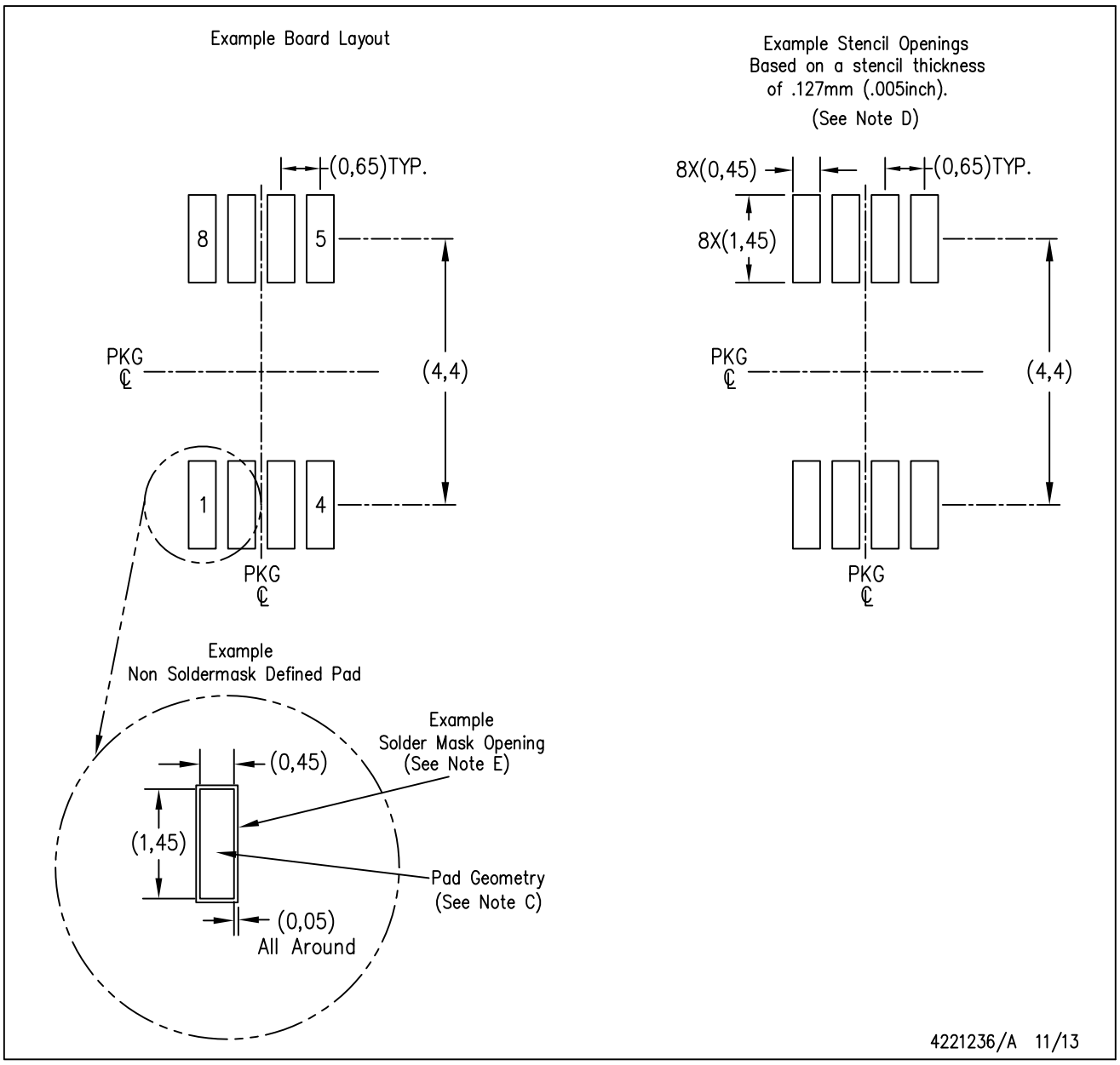
DGK (S–PDSO–G8) PLASTIC SMALL–OUTLINE PACKAGE



4073329/E 05/06

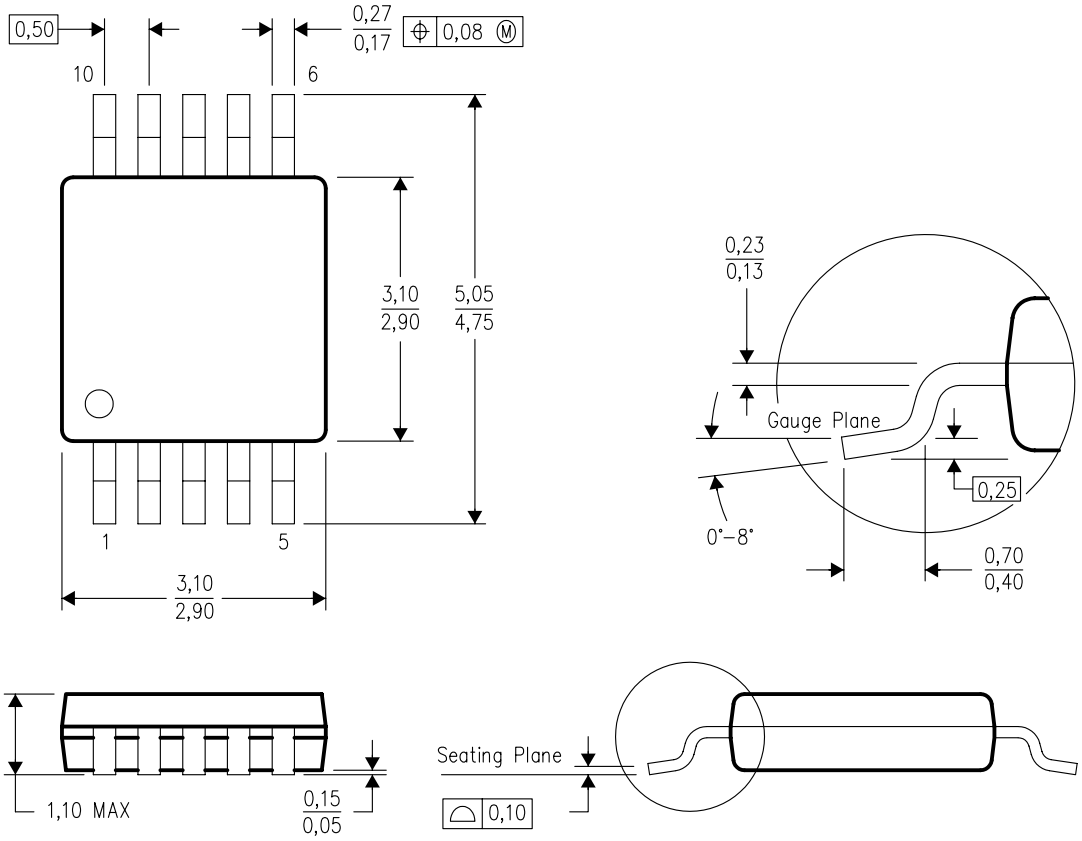
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
E. Falls within JEDEC MO–187 variation AA, except interlead flash.

DGK (S–PDSO–G8) PLASTIC SMALL OUTLINE PACKAGE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

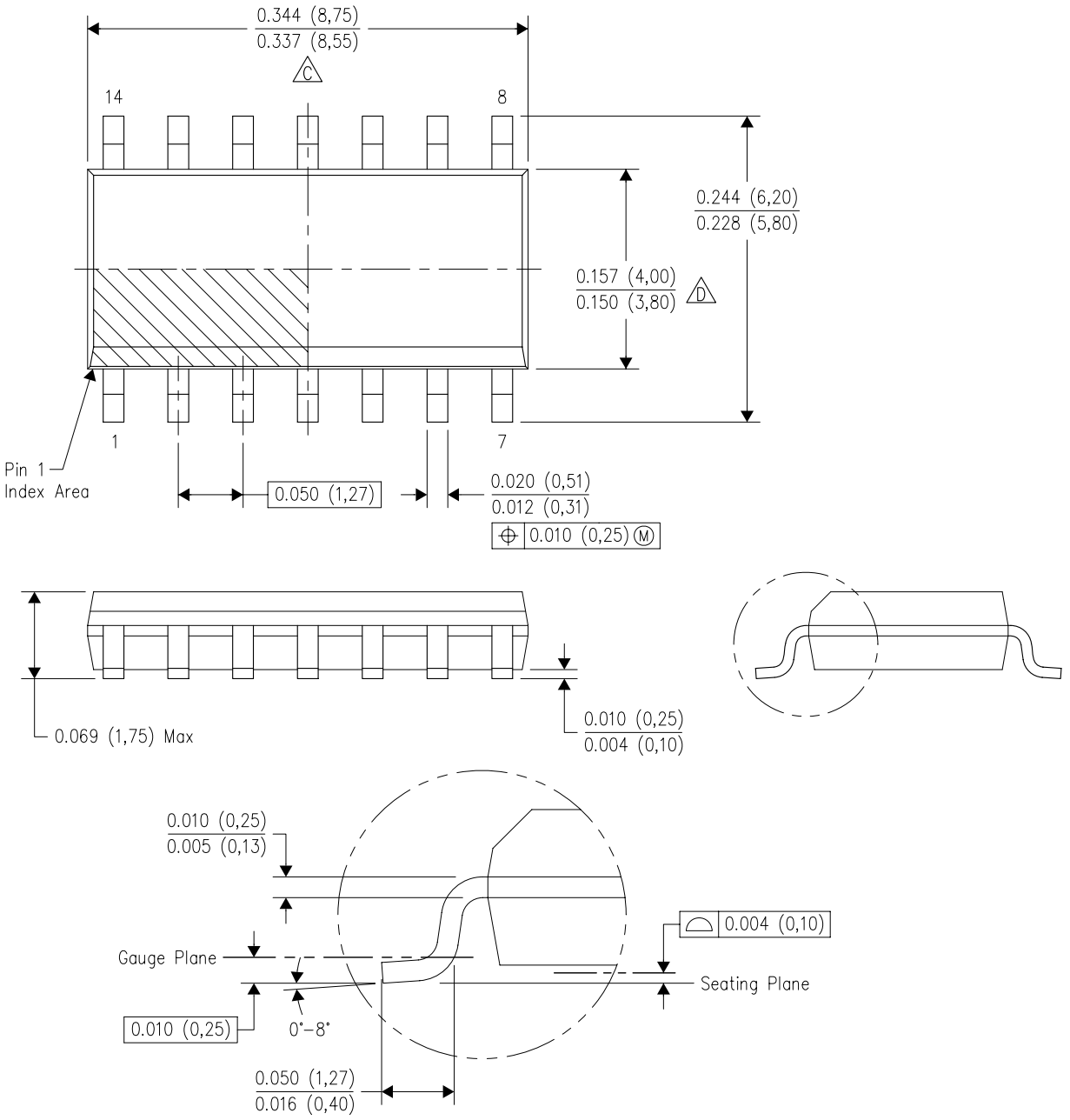
DGS (S–PDSO–G10) PLASTIC SMALL–OUTLINE PACKAGE



4073272/C 02/04

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion.
D. Falls within JEDEC MO–187 variation BA.

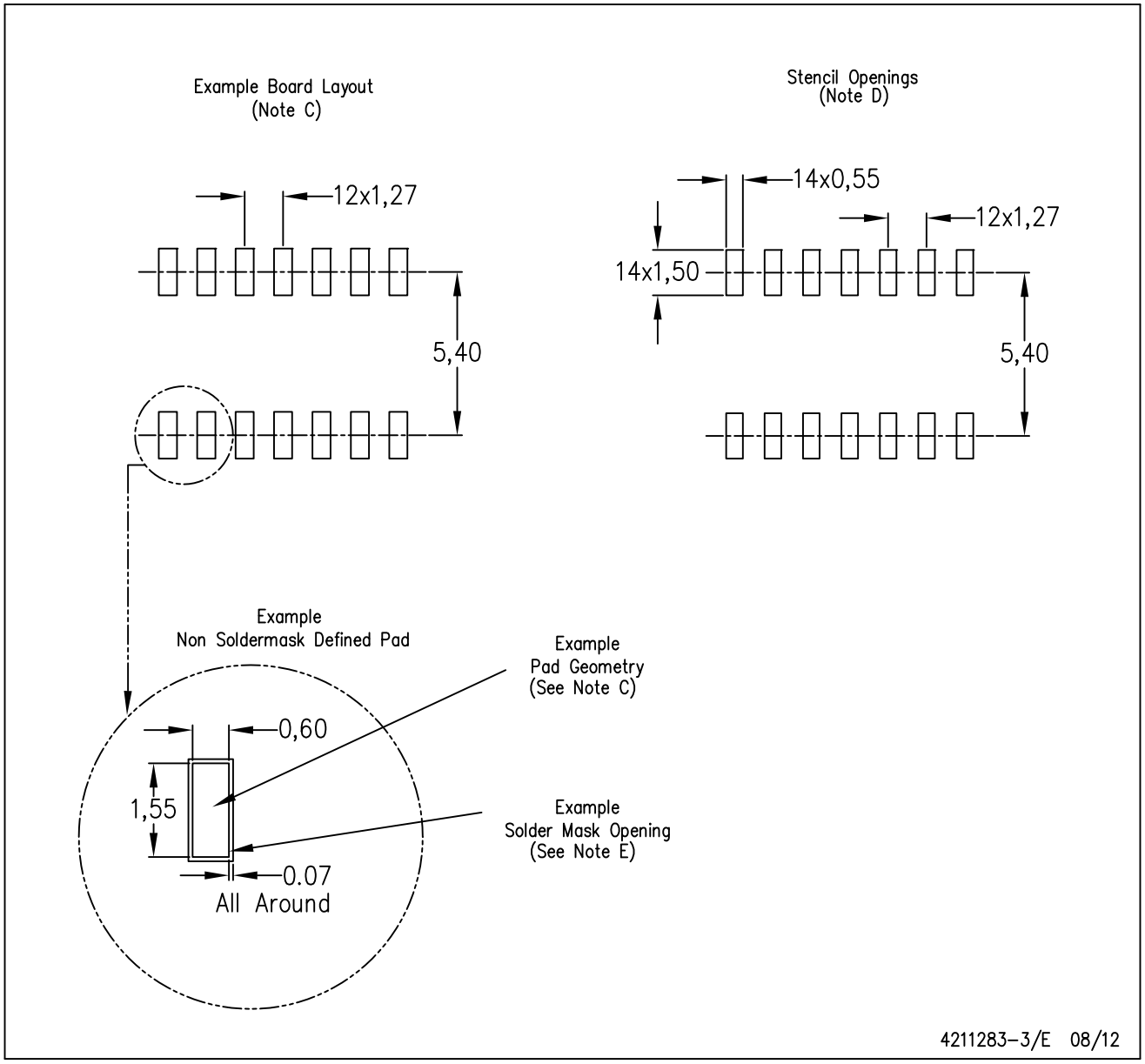
D (R–PDSO–G14) PLASTIC SMALL OUTLINE



4040047–5/M 06/11

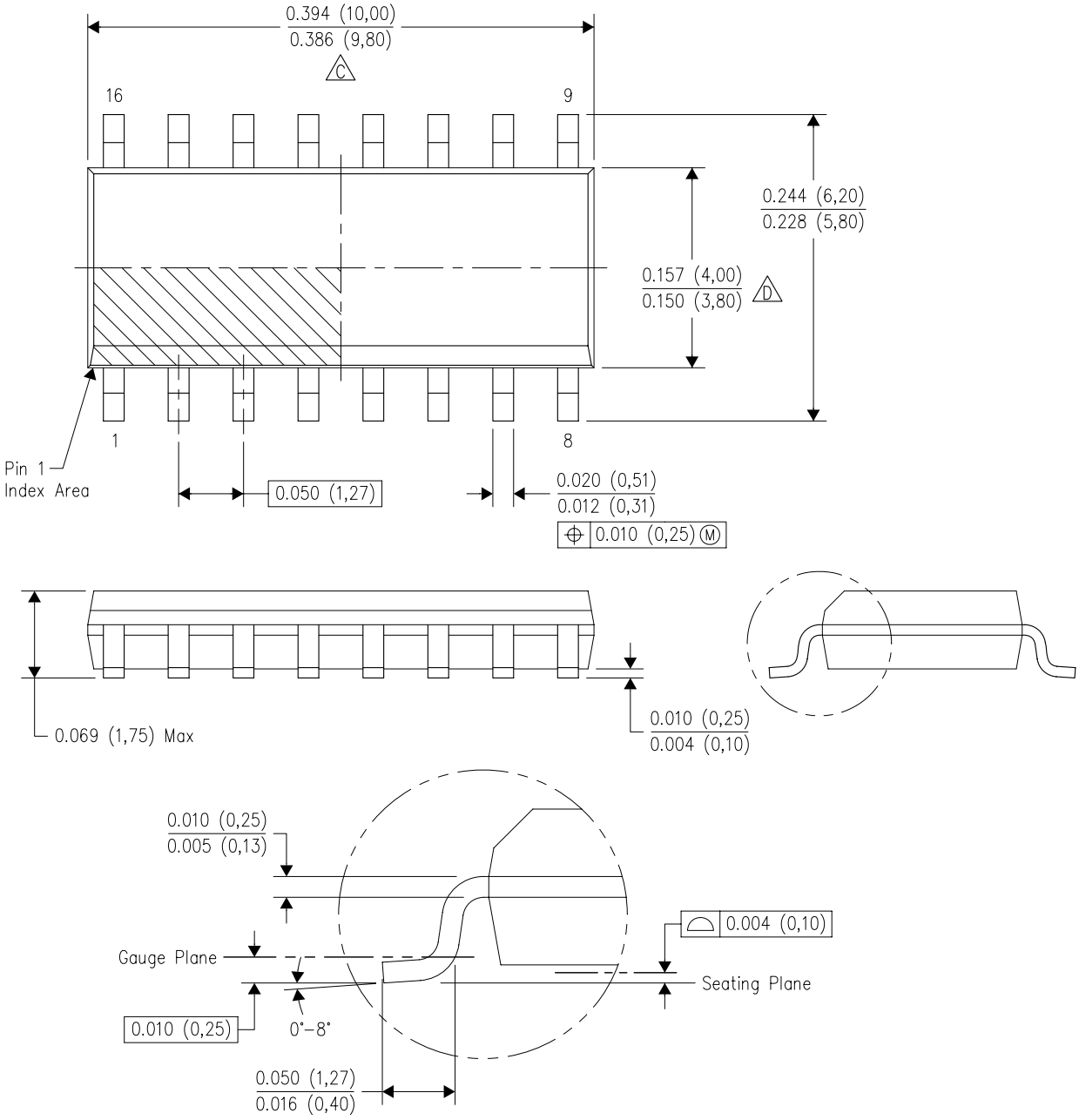
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AB.

D (R–PDSO–G14) PLASTIC SMALL OUTLINE



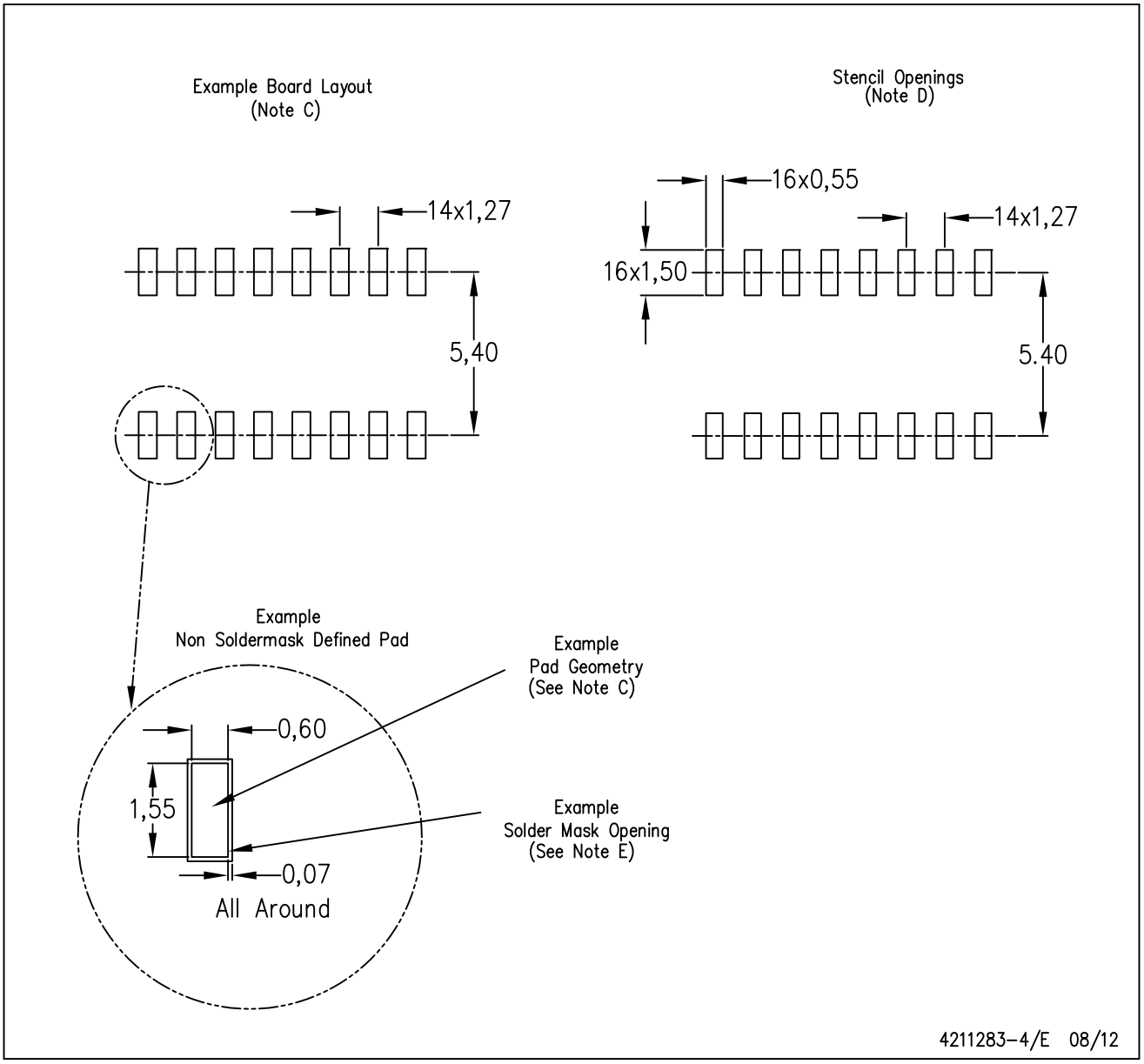
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

D (R–PDSO–G16) PLASTIC SMALL OUTLINE



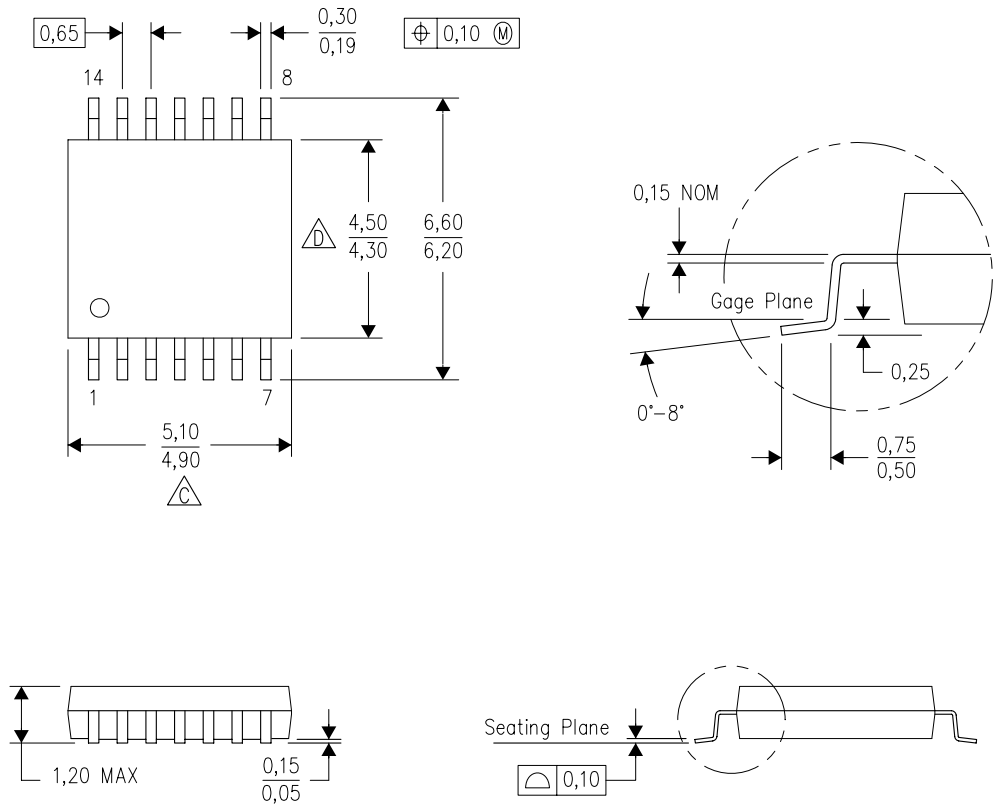
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AC.

D (R–PDSO–G16) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

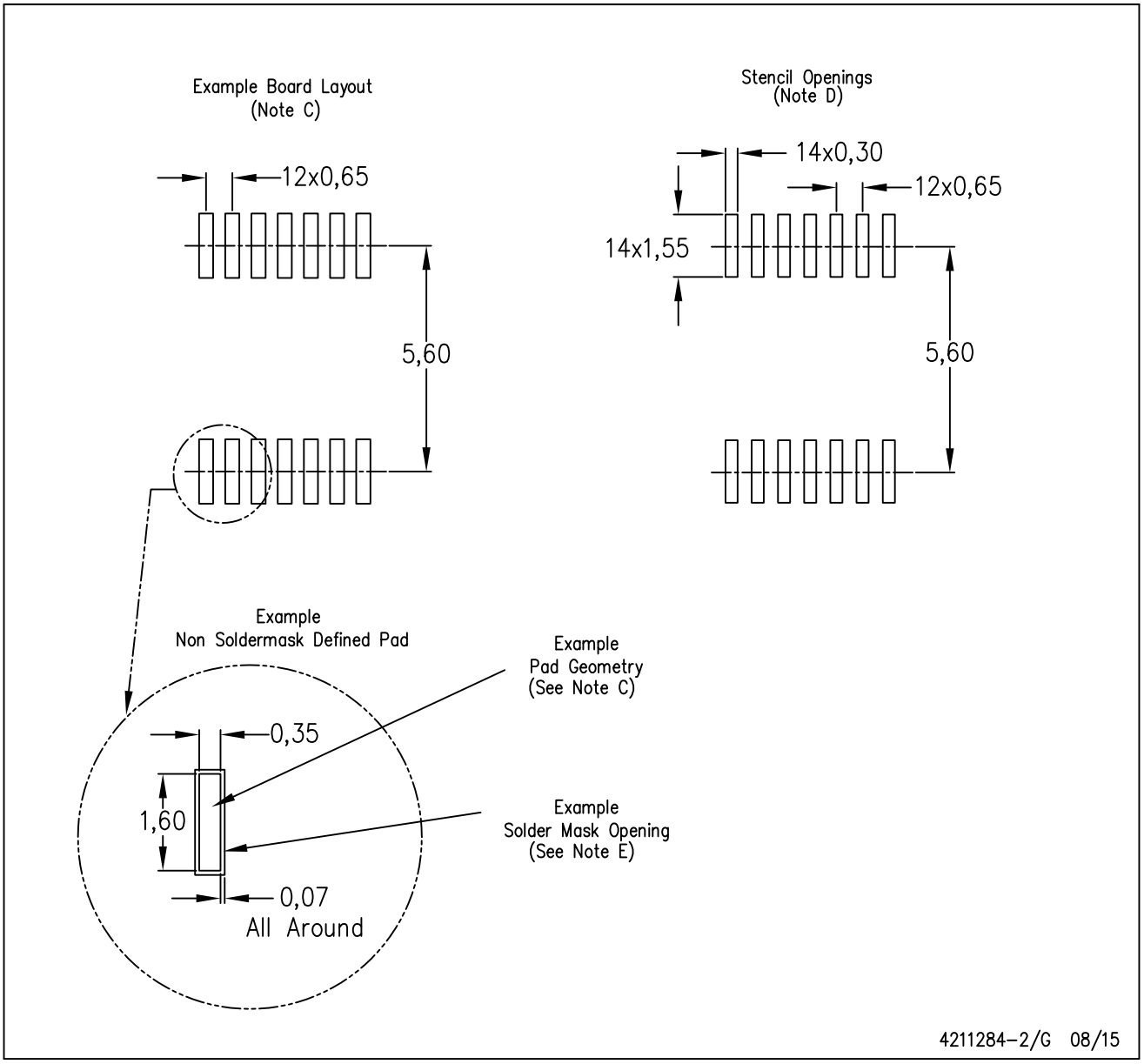
PW (R–PDSO–G14) PLASTIC SMALL OUTLINE



4040064–3/G 02/11

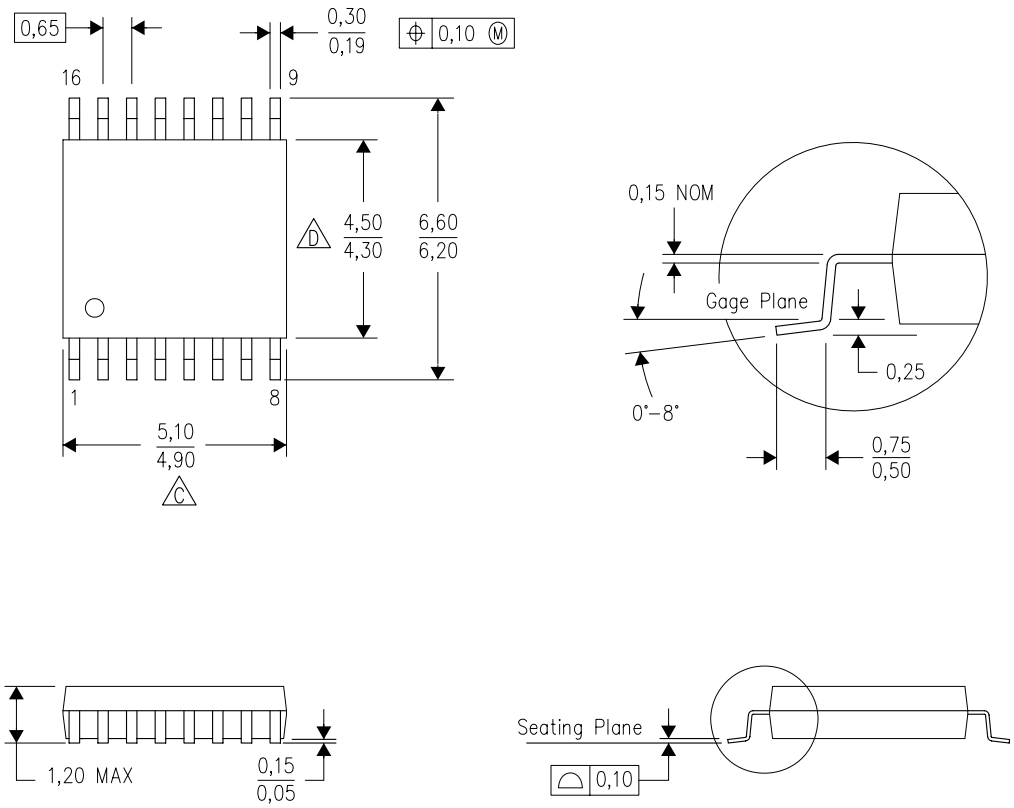
NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
E. Falls within JEDEC MO–153

PW (R–PDSO–G14) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

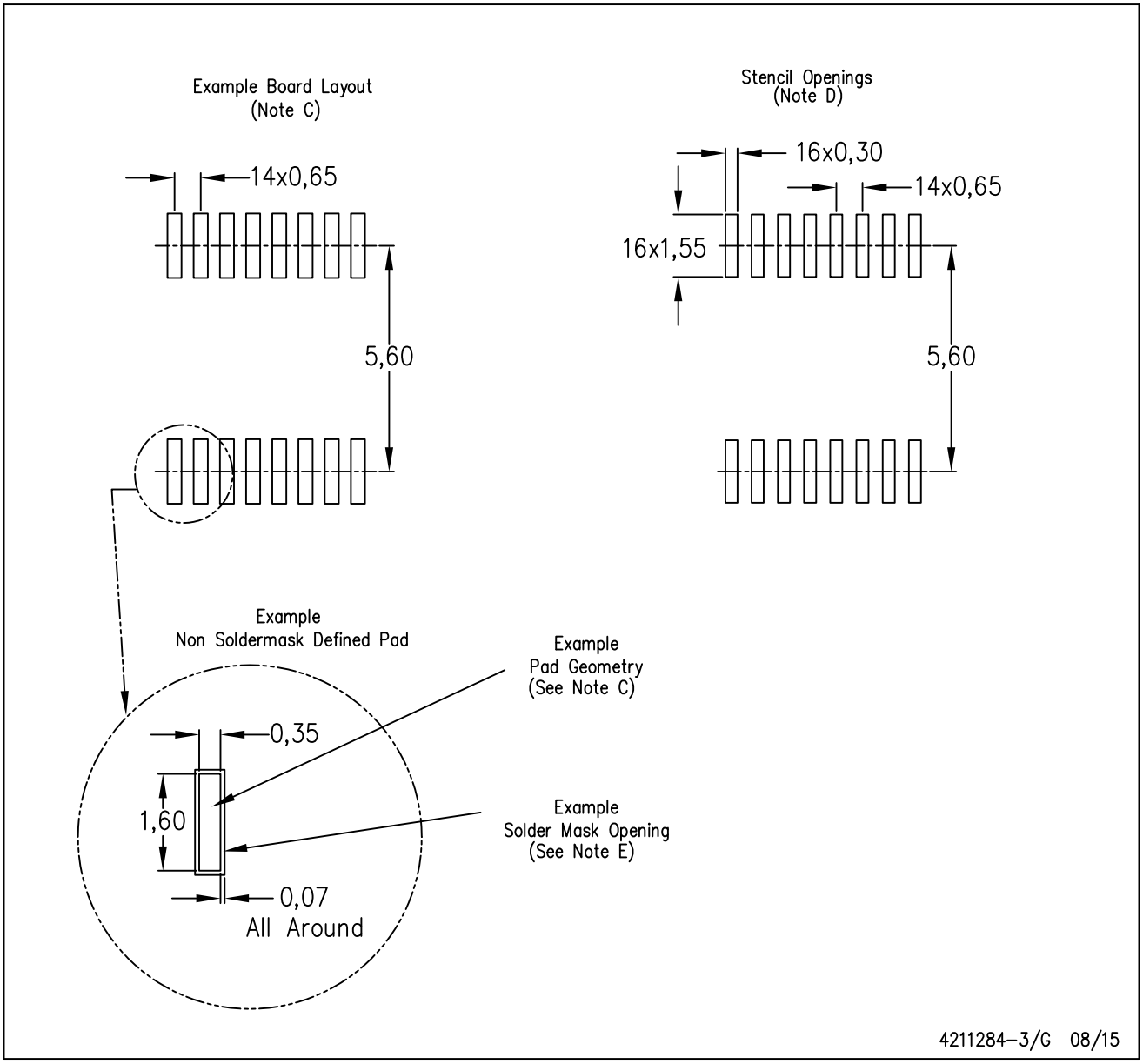
PW (R–PDSO–G16) PLASTIC SMALL OUTLINE



4040064–4/G 02/11

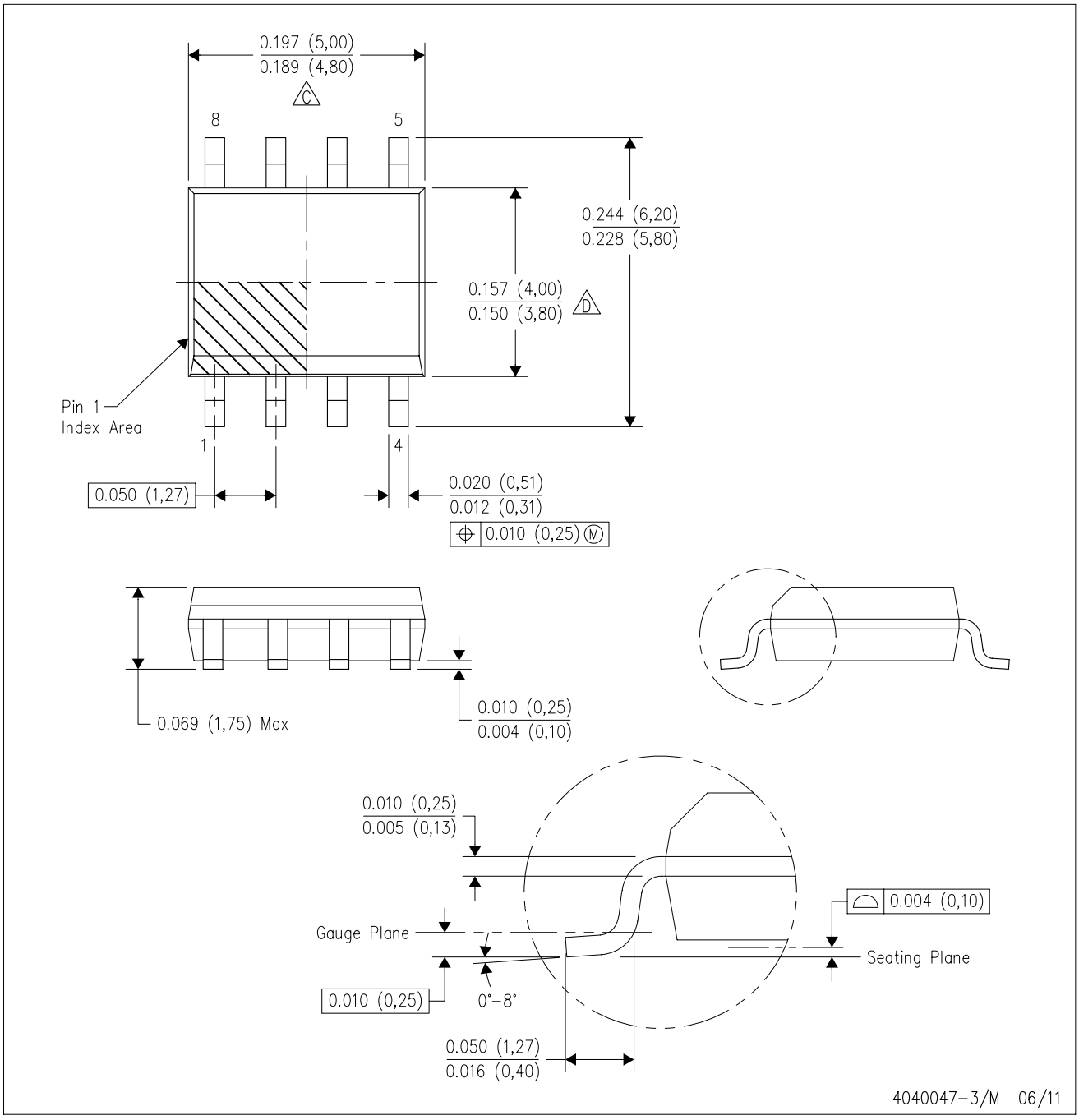
NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
E. Falls within JEDEC MO–153

PW (R–PDSO–G16) PLASTIC SMALL OUTLINE



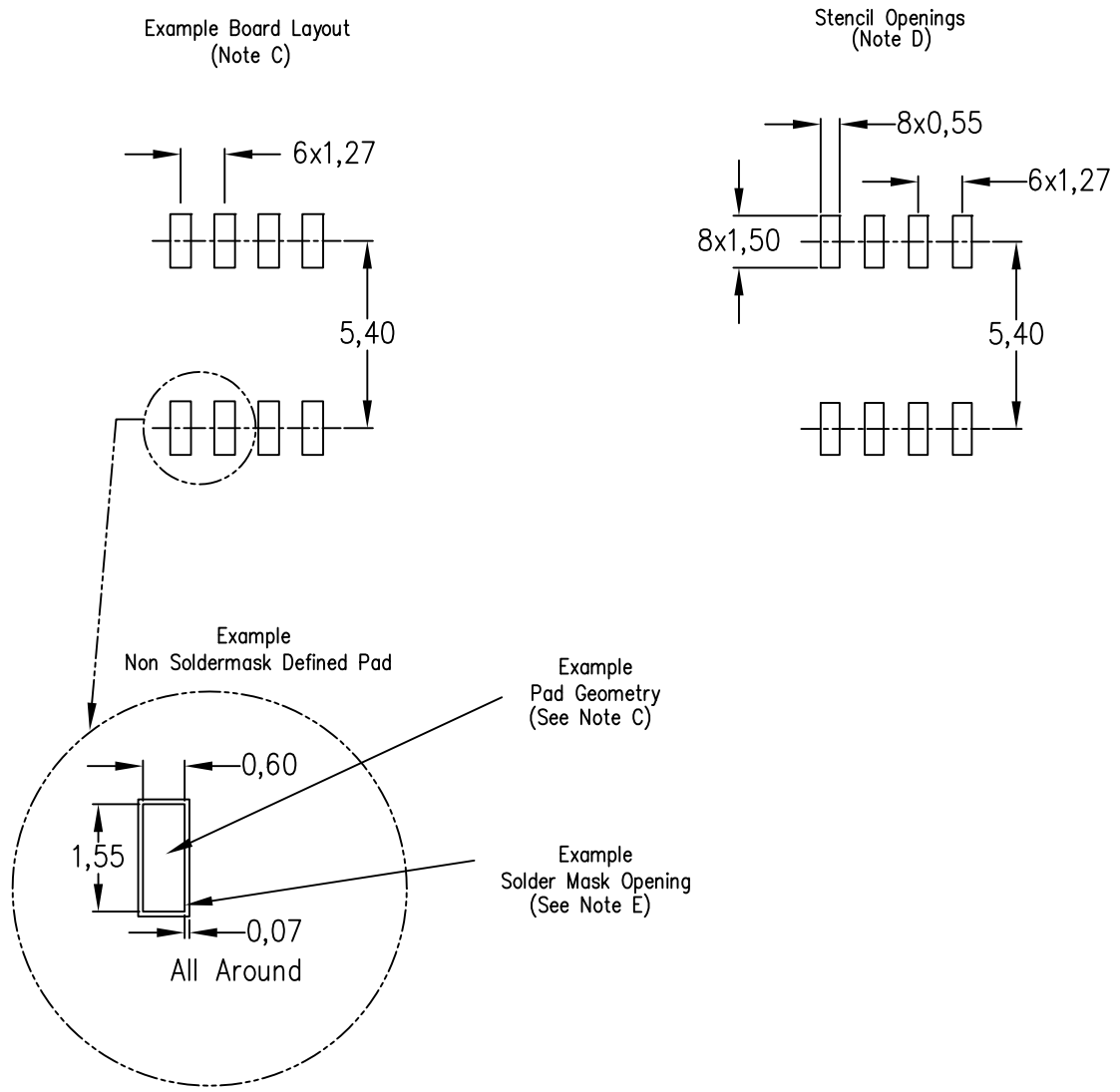
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AA.

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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